August 2013



FAN54300 — USB-Compliant, Dual-Power Input, Single-Cell, Li-Ion Switching Charger with USB-OTG Boost Regulator

Features

- Fully Integrated, High-Efficiency Charger for Single-Cell Li-Ion and Li-Polymer Battery Packs
- Accepts USB or Dedicated Power Input Source
- 5 V, 300 mA Boost Mode for USB OTG from 2.5 to 4.5 V Battery Input
- $\hfill \$ Charge Voltage Accuracy: $\pm 0.5\%$ at $T_A=25^\circ C$ $\pm 1\%$ from $T_A=0$ to $125^\circ C$
- ±5% USB Input Current Regulation Accuracy
- ±5% Charge Current Regulation Accuracy
- 20 V Absolute Maximum Input Voltage
- 9.5 V Maximum Input Operating Voltage on VIN Pin, 6.5 V Maximum on VBUS Pin
- Up to 1.5 A Maximum Charge Rate
- Programmable Charge and Mode through High-Speed I²C Interface (3.4 Mb/s) with Fast Mode Plus Compatibility
 - Input Current
 - Fast-Charge / Termination Current
 - Charger Voltage
 - Safety Timer
 - Termination Enable
- 3 MHz Synchronous Buck PWM Controller with Wide Duty Cycle Range
- Small Footprint, 1 μH, External Inductors
- Safety Timer with Reset Control
- Weak Input Sources Accommodated by Reducing Charging Current to Maintain Minimum V_{BUS} Voltage
- Low Reverse Leakage from Battery Drain to VBUS or VIN
- Programmable LED Drive for Charge Indication
- Register and Slave Addresses Compatible with FAN540X and FAN542X Families

Description

The FAN54300 combines two highly integrated switch-mode chargers and a boost regulator to minimize single-cell Li-Ion charging time from a USB and/or auxiliary power source.

Charging parameters and operating modes are programmable through an I^2C Bus® interface that operates up to 3.4 Mbps. The charger and boost regulator circuits switch at 3 MHz to minimize the size of the external passive components.

The FAN54300 provides battery charging in three phases: conditioning, constant current, and constant voltage.

To ensure USB compliance and minimize charging time, the USB input current is limited to the value set through the l^2C host. Charge termination is determined by a programmable minimum current level. A safety timer with reset control provides a safety backup for the l^2C host.

The IC automatically restarts the charge cycle when the battery falls below an internal threshold. If the input source is removed, the IC enters a high-impedance mode, with leakage from the battery to the input prevented. Charge status is reported back to the host through the I^2C port. Charge current is reduced when the die temperature reaches $120^{\circ}C$.

The FAN54300 can operate as a boost regulator on command from the system. The boost regulator includes a soft-start that limits inrush current from the battery.

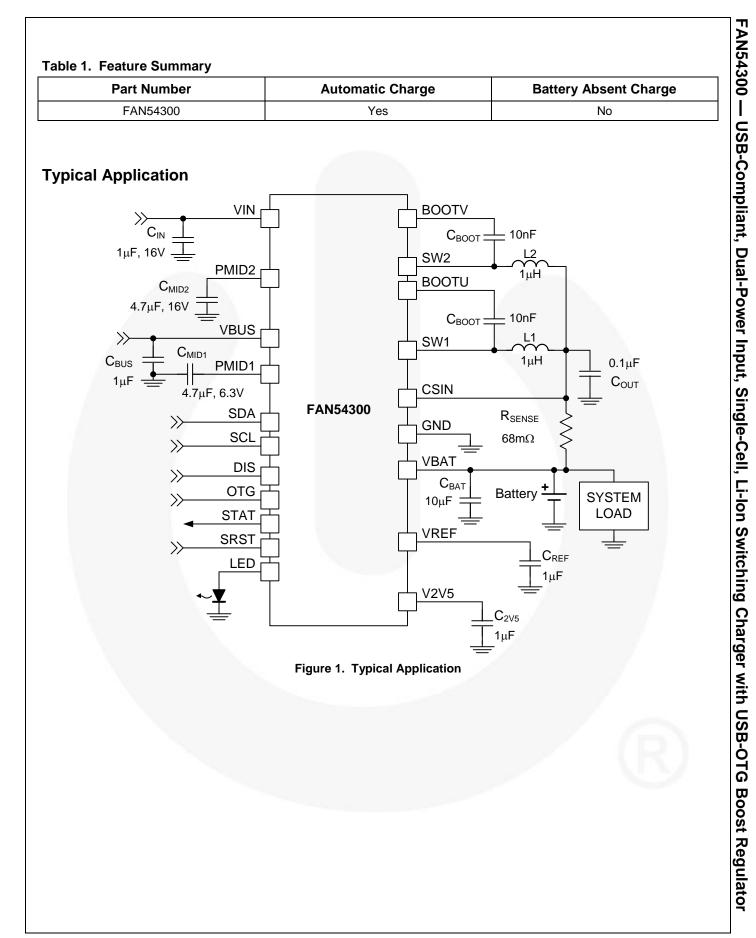
The FAN54300 is available in a 30-bump, 0.4 mm pitch, wafer-level, chip-scale package (WLCSP).

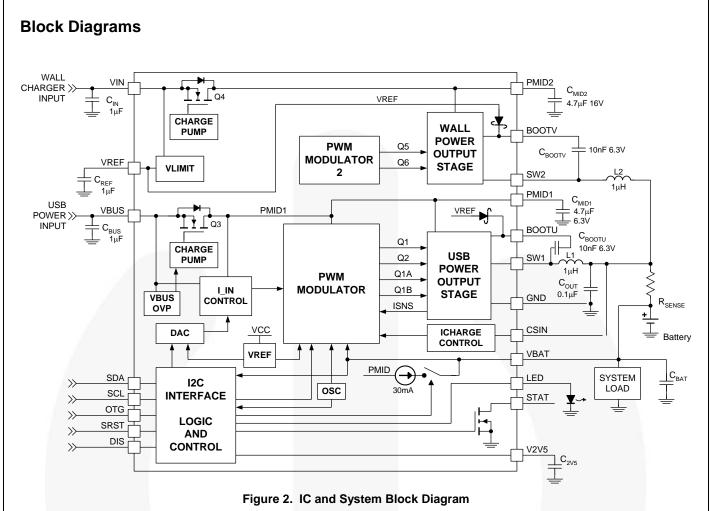
Applications

- Cell Phones, Smart Phones, PDAs
- Digital Cameras
- Portable Media Players

| <u> </u> | | | | | | |
|-------------------------------|-------------|--|---------------|--|--|--|
| Part Number Temperature Range | | Package | Packing | | | |
| FAN54300UCX | -40 to 85°C | 30-Ball, WLCSP, 5x6 Array, 0.4mm Pitch, 586 μm Package Height | Tape and Reel | | | |

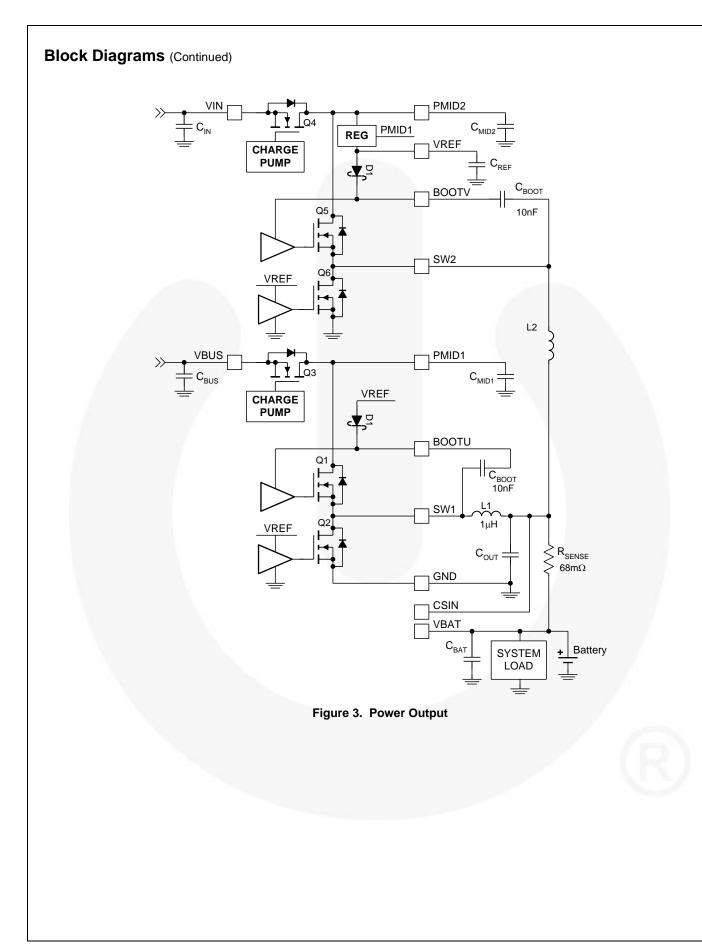
Ordering Information





| Table 2. | Recommended | External | Components |
|----------|-------------------|----------|-------------|
| | 1.000011111011000 | EXCOLUCI | oomponionto |

| Component | Description | Vendor | Parameter | Тур. | Units |
|------------------------------------|-------------------------------|------------------------|-----------|------|-------|
| | Charge Currents to 1 A: | Murata: LQM2MPN1R0M | L | 1.0 | μH |
| L1, L2: | L2: | Murata. EQMZIVIENTROM | DCR | 85 | mΩ |
| LI, LZ. | | Murata: LQM2HPN1R0M | L | 1.0 | μH |
| | 1 μH, 20%, 1.6 A, 2520 | | DCR | 55 | mΩ |
| | 10 μF, 20%, 6.3 V, X5R, 0603 | Murata: GRM188R60J106M | С | 10 | μF |
| | 4.7 μF, 10%, 16 V, X5R, 0805 | Murata: GRM21BR61C475K | С | 4.7 | μF |
| C _{IN} , C _{BUS} | 1.0 μF, 10%, 16 V, X5R, 0603 | Murata GRM188R61E105K | С | 1.0 | μF |
| C _{BOOT} | 10 nF, 10%, 6.3 V, X5R, 0201 | Murata GRM033R70J103K | С | 10 | nF |
| C _{OUT} | 0.1 μF, 10%, 6.3 V, X5R, 0201 | Murata GRM033R60J104K | С | 0.1 | μF |
| C_{2V5}, C_{REF} | 1μF, 10%, 6.3 V, X5R, 0402 | Murata GRM155R60J105M | С | 1.0 | μF |



Pin Configuration

| BOOTV | VREF | V2V5 | SDA | BOOTU |
|-------|-------|------|------|-------|
| (A1) | (A2) | (A3) | (A4) | (A5) |
| V | VIN | | VB | US |
| (B1) | (B2) | (B3) | (B4) | (B5) |
| PM | PMID2 | | PM | ID1 |
| (C1) | (C2) | (C3) | (C4) | (C5) |
| SV | V2 | DIS | SW1 | |
| (D1) | (D2) | (D3) | (D4) | (D5) |
| | | GND | | |
| E1) | (E2) | (E3) | (E4) | (E5) |
| LED | OTG | CSIN | VBAT | STAT |
| (F1) | (F2) | (F3) | (F4) | (F5) |

Figure 4. Pin Assignments (Top View)

Pin Definitions

| Pin # | Name | Description |
|--------|-------|---|
| A1 | BOOTV | BOOT . High-side NMOS driver supply. Connect a 10nF capacitor from SW2 to this pin. |
| A2 | VREF | Bias Regulator Output . Connect to a 1 μ F capacitor to PGND. This pin supplies the internal gate drive and power supply to the IC while charging. Up to 5 mA of current can be provided from this pin to drive external circuits. This pin is active when either V _{IN} or V _{BUS} are above V _{BAT} . |
| A3 | V2V5 | 2.5 V Regulator . Connect to a 1 μ F capacitor to PGND. Up to 5 mA can be provided from this pin to drive external circuits. This regulator is powered only when VIN is connected. |
| A4 | SDA | I ² C Interface Serial Data. This pin should not be left floating. |
| A5 | BOOTU | BOOT. High-side NMOS driver supply. Connect a 10 nF capacitor from SW1 to this pin. |
| B1, B2 | VIN | Charger Input Voltage. Bypass with a minimum of 1 µF, 16 V capacitor to GND. |
| B3 | SCL | I ² C Interface Serial Clock. This pin should not be left floating. |
| B4, B5 | VBUS | USB Input Voltage. Bypass with a 1 μ F, 16 V capacitor to GND. |
| C1, C2 | PMID2 | Power Input Voltage for VIN Power Source . Power input to the charger regulator, bypass point for the VIN input current sense, and high-voltage input switch. Bypass with a minimum of 4.7 μ F, 16 V capacitor to PGND. |
| C3 | SRST | Safety Reset. When LOW, both safety registers are reset to their default values. When HIGH, the safety registers reset when V_{BAT} drops below V_{SHORT} . |
| C4, C5 | PMID1 | Power Input Voltage for VBUS Power Source . Power input to the VBUS switching charger regulator, bypass point for the VBUS input current sense, and high-voltage input switch. Bypass with a minimum of 4.7 μ F, 6.3 V capacitor to PGND. |
| D1, D2 | SW2 | Switching Node for VIN Charger. Connect to the output inductor. |
| D3 | DIS | Charge Disable . When this pin is HIGH, charging is disabled and no timers are reset. When LOW, charging is controlled by the I ² C registers. This pin does not affect the 32-second timer. |
| D4, D5 | SW1 | Switching Node for VBUS Charger and OTG Boost. Connect to the output inductor. |
| E1–E5 | GND | Ground . Power return for gate drive and power transistors as well as IC signal ground. The connection from this pin to the bottoms of the C_{PMID} capacitors should be as short as possible. |
| F1 | LED | Light Emitting Diode Output . Up to 5 mA current source drive from the active PMID indicates the battery is charging. |

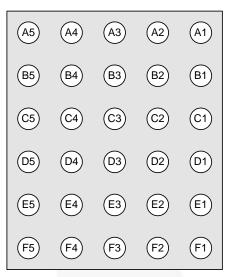


Figure 5. Pin Assignments (Bottom View)

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| Charger with USB-C |
| Charger with USB-C |
| Charger with USB-OTG Boost |
| Charger with USB-C |
| Charger with USB-OTG Boost |
| Charger with USB-OTG Boost Regulate |

| F5 | STAT | process. | |
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| Pin # | Name | Description |
|-------|------|---|
| F2 | OTG | On The Go . When unattended charging is indicated, the level on this pin sets the I_{BUS} current limit. This pin is also used to put the IC into Boost Mode. |
| F3 | CSIN | Current-Sense Input . Connect to sense resistor in series with the battery. The IC uses this node to sense current into the battery. Bypass this pin with a 0.1 μ F capacitor to PGND. |
| F4 | VBAT | Battery Voltage. Connect to the positive (+) terminal of the battery pack. Bypass with a 10 μ F capacitor to PGND. |
| F5 | STAT | Status. Open-drain output indicating charge status. The IC pulls this pin LOW when charging is in |

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

| Symbol | | Parameter | Min. | Max. | Unit |
|-------------------------|--|---------------------------------------|-----------|--------------------|------|
| | | Continuous | -1.4 | 20.0 | N |
| V _{BUS} | VBUS Voltage | Pulsed, 100 ms Maximum Non-Repetitive | -2.0 20.0 | | V |
| VIN | VIN Voltage | | -2.0 | 20.0 | V |
| V _{BOOTU} | BOOTU Voltage | | -0.7 | 20.0 | V |
| V _{BOOTV} | BOOTV Voltage | | -0.7 | 20.0 | V |
| V_{PMID1} | PMID1 Voltage | | -1.0 | 20.0 | V |
| V _{SW1} | SW1 Voltage | | -0.7 | 6.5 | V |
| V _{PMID2} | PMID2 Voltage | 1 | -1.0 | 20.0 | V |
| V _{SW2} | SW2 Voltage | | -0.7 | 12.0 | V |
| Vo | Other Pins | | -0.3 | 6.5 ⁽¹⁾ | V |
| dV _{BUS} dt | Maximum Rate of V _{BUS} Increase | Above 5.5 V when IC Enabled | | 4 | V/µs |
| dV _{IN} dt | Maximum Rate of V _{IN} Increase A | Above 9.5 V when IC Enabled | | 4 | V/µs |
| ESD | Electrostatic Discharge | Human Body Model per JESD22-A114 | 2 | .0 | kV |
| ESD | Protection Level | Charged Device Model per JESD22-C101 | 1 | .5 | kV |
| TJ | Junction Temperature | | -40 | +150 | °C |
| T _{STG} | Storage Temperature | | -65 | +150 | °C |
| TL | Lead Soldering Temperature, 10 |) Seconds | | +260 | °C |

Note:

1. Lesser of 6.5 V or V_{REF} + 0.3 V.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

| Symbol | Parameter | Min. | Max. | Units |
|------------------|----------------------|------|------|-------|
| V _{BUS} | VBUS Supply Voltage | 4 | 6 | V |
| V _{IN} | VIN Supply Voltage | 4.0 | 9.5 | V |
| T _A | Ambient Temperature | -30 | +85 | °C |
| TJ | Junction Temperature | 0 | +125 | °C |

Thermal Properties

Junction-to-ambient thermal resistance is a function of application and board layout. This data is measured with four-layer 2s2p boards in accordance to JEDEC standard JESD51. Special attention must be paid not to exceed junction temperature $T_{J(max)}$ at a given ambient temperate T_A .

| Symbol | Parameter | Typical | Unit |
|--|------------------------------------|---------|------|
| θ _{JA} Junction-to-Ambient Thermal Resistance | | 60 | °C/W |
| θ_{JB} | Junction-to-PCB Thermal Resistance | 20 | °C/W |

Electrical Specifications

Unless otherwise specified: circuit of Figure 1, recommended operating temperature range for T_J and T_A , V_{BUS} or $V_{IN} = 5.0$ V, HZ1, HZ2, OPA_MODE = 0, (Charger Mode). SCL, SDA, OTG = 0 or 1.8 V. Typical values are for $T_J = 25^{\circ}$ C.

| Symbol | Parameter | Conditions | Min. | Тур. | Max. | Units |
|---------------------|---|---|------|------|------|---------|
| Power Su | ipplies | | | | | |
| | | PWM Switching, Open Battery, TE=0 | | 33 | | mA |
| | VBUS Current | PWM Not Switching (V _{BAT} > V _{OREG}) | | 3.6 | | mA |
| I _{VBUS} | | $0^{\circ}C < T_{J} < 85^{\circ}C, HZ1 = 1, V_{BAT} > V_{LOWV}$ | | 350 | 500 | μA |
| | | $0^{\circ}C < T_J < 85^{\circ}C, HZ1$ = 1, $V_{BAT} < V_{LOWV}, 32S$ Mode | | 350 | 500 | μA |
| | | PWM Switching, Open Battery, TE=0 | | 33 | | mA |
| | | PWM Not Switching (VBAT>VOREG) | 100 | 2.6 | | mA |
| I _{VIN} | VIN Current | $0^{\circ}C < T_J < 85^{\circ}C, HZ2 = 1, V_{IN} > V_{LOWV}$ | | 350 | 500 | μA |
| | | $0^{\circ}C < T_J < 85^{\circ}C, HZ2 = 1, V_{IN} < V_{LOWV}, 32S \; Mode$ | | 350 | 500 | μA |
| I _{BAT} | | $0^{\circ}C < T_J < 85^{\circ}C$, HZ1=HZ2 = 1 or DIS=1, V _{BAT} = 4.2 V | | | 20 | μA |
| | Battery Discharge Current in High-Z Mode | $\begin{array}{l} 0^{\circ}C < T_{J} < 85^{\circ}C, \ V_{BAT} = 4.2 \ V, \ V_{IN} = \\ V_{BUS} = \ Open \ or \ GND, \ HZ1 = HZ2 = 1, \\ SDA = SCL = 1.8 \ V, \ No \ I^{2}C \ Traffic \end{array}$ | | | 30 | μA |
| Charger \ | /oltage Regulation | | | | | |
| | Charge Voltage Range | | 3.5 | | 4.4 | V |
| V _{OREG} | Charge Voltage Accuracy | $T_A = 25^{\circ}C$ | -0.5 | | +0.5 | % |
| | | $T_J = 0$ to 125°C | -1 | | +1 | % |
| Charging | Current Regulation | | | | | |
| | Output Charge Current Range | $V_{LOWV} < V_{BAT} < V_{OREG},$ $V_{BUS} > V_{SLP}, R_{SENSE} = 68 m\Omega$ | 550 | | 1500 | mA |
| OCHRG | Charge Current Accuracy | $20 \text{ mV} \leq V_{IREG} \leq 40 \text{ mV}$ | 92 | 97 | 102 | % of |
| | Across R _{SENSE} | V _{IREG} > 40 mV | 94 | 97 | 100 | Setting |
| Weak-Bat | ttery Detection | | 1 | | | |
| V _{LOWV} | Weak-Battery Threshold Accuracy | $3.4 \le V_{LOWV} \le 3.7$ | -5 | | +5 | % |
| | Weak Battery Deglitch Time | Rising Voltage, 2 mV Overdrive | | 30 | | ms |
| Logic Lev | els: DIS, SDA, SCL, OTG | | | | | |
| VIH | HIGH-Level Input Voltage | | 1.05 | | | V |
| VIL | LOW-Level Input Voltage | | | | 0.4 | V |
| I _{IN} | Input Bias Current | Input Tied to GND or V _{BAT} | | 0.01 | 1.00 | μA |
| Charge T | ermination Detection | | 1 | | | () I - |
| | Termination Current Range | $\label{eq:VBAT} \begin{split} V_{\text{BAT}} &> V_{\text{OREG}} - V_{\text{RCH}}, V_{\text{BUS}} > V_{\text{SLP}}, \\ R_{\text{SENSE}} &= 68 \; \text{m}\Omega \end{split}$ | 50 | | 400 | mA |
| l | Termination Ourrent Accurate | $[V_{CSIN}-V_{BAT}]$ from 3 mV to 20 mV | -25% | | +25% | |
| I _(TERM) | Termination Current Accuracy | $[V_{CSIN}-V_{BAT}]$ from 20 mV to 40 mV | -5% | | +5% | |
| | Termination Current Deglitch Time | 2 mV Overdrive | | 30 | | ms |

FAN54300 — USB-Compliant, Dual-Power Input, Single-Cell, Li-Ion Switching Charger with USB-OTG Boost Regulator

Electrical Specifications (Continued)

Unless otherwise specified: circuit of Figure 1, recommended operating temperature range for T_J and T_A , V_{BUS} or $V_{IN} = 5.0$ V, HZ1, HZ2, OPA_MODE = 0, (Charger Mode). SCL, SDA, OTG = 0 or 1.8V. Typical values are for $T_J = 25^{\circ}$ C.

| Symbol | Parameter | Conditions | Min. | Тур. | Max. | Units |
|-------------------------|--|---|------|-------|------|-------|
| VBUS Inp | ut Power Source Detection | 1 | | 1 | | 1 |
| V _{BUS(MIN)1} | V _{BUS} Input Voltage Rising | To Start V _{BUS} Validation | 4.20 | 4.30 | 4.40 | V |
| V _{BUS(MIN)2} | Min. V _{BUS} to Pass Validation | During V _{BUS} Validation Period | 4.00 | 4.08 | 4.15 | V |
| V _{BUS(MIN)3} | Min. V _{BUS} During Charge | During Charging | 3.64 | 3.71 | 3.78 | V |
| tvbus_valid | V _{BUS} Validation Time | | | 30 | | ms |
| VBUSLOAD | V _{BUS} Load | $V_{BUS} = 5 V$, Applied at V_{BUS} Validation | | 50 | | mA |
| VIN Input | Power Source Detection | • | L | | I. | |
| VIN(MIN)1 | VIN Input Voltage Rising | To Start V _{IN} Validation | 4.20 | 4.30 | 4.40 | V |
| V _{IN(MIN)2} | Min. V _{IN} to Pass Validation | During V _{IN} Validation Period | 4.00 | 4.08 | 4.15 | V |
| V _{IN(MIN)3} | Min. V _{IN} During Charge | During Charging | 3.64 | 3.71 | 3.78 | V |
| t _{VBUS_VALID} | V _{IN} Validation Time | | | 30 | | ms |
| VINLOAD | V _{IN} Load | $V_{IN} = 5 V$, Applied at V_{IN} Validation | | 50 | | mA |
| Input Curr | ent Limit | · | | | | |
| | VBUS Input Current-Limit | I _{BUS} set to 100 mA | 88 | 93 | 98 | |
| IBUSLIM | Threshold | I _{BUS} set to 500 mA | 450 | 475 | 500 | mA |
| V _{2V5} 2.5V I | inear Regulator | • | | | | |
| | 2.5 V Regulator Output | I_{2V5} from 0 to 5 mA, V_{IN} > 4.75 V | 2.35 | 2.50 | 2.65 | V |
| V_{2V5} | Current Limit | | 6 | 8 | | mA |
| V _{REF} Bias | Generator | · | | | | |
| N/ | Bias regulator voltage | $V_{IN} > V_{IN(MIN)}$ | 3.5 | | 6.0 | V |
| V_{REF} | current limit | | 10 | 15 | | mA |
| Battery Re | charge Threshold | | | | | |
| N | Recharge Threshold | Below V _(OREG) | 100 | 120 | 150 | mV |
| V _{RCH} | Deglitch Time | VBAT falling below V _{RCH} threshold | | 130 | | ms |
| STAT Out | put | | | | | |
| V _{STAT(OL)} | STAT Output LOW | I _{STAT} = 10 mA | | | 0.4 | V |
| I _{STAT(OH)} | STAT High Leakage Current | V _{STAT} = 5 V | | | 1 | μA |
| LED Outp | ut | | | | | |
| I _{LED(ON)} | LED Output Current Accuracy | V_{LED} from 1.5 to 3.5 V, Max. (V_{REF} , V_{BAT}) – V_{LED} > 100 mV | -30 | | +30 | % |
| I _{LED(OFF)} | LED Off-State Leakage Current | V _{LED} = 0 V | | | 1 | μA |
| Battery De | etection | | | | | 1 |
| I _{DETECT} | Battery Detection Current Before Charge Complete (Sink Current) ⁽²⁾ | Begins After Termination Detected and $V_{BAT} \leq V_{OREG} - V_{RCH}$ | | -0.45 | | mA |
| t _{DETECT} | Battery Detection time | | | 262 | | ms |

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Electrical Specifications (Continued)

Unless otherwise specified: circuit of Figure 1, recommended operating temperature range for T_J and T_A , V_{BUS} or $V_{IN} = 5.0$ V, HZ1, HZ2, OPA_MODE = 0, (Charger Mode). SCL, SDA, OTG = 0 or 1.8 V. Typical values are for $T_J = 25^{\circ}$ C.

| Symbol | Parameter | Conditions | Min. | Тур. | Max. | Units | |
|-----------------------|---|--|------|------|------|-------|--|
| Sleep Cor | nparator | | 1 | L | 1 | | |
| V_{SLP} | Sleep Mode Entry Threshold, $V_{BUS} - V_{BAT}$ or $V_{IN} - V_{BAT}$ | $2.3 \text{ V} \leq \text{V}_{BAT} \leq \text{V}_{OREG}, \text{V}_{PWRIN} \text{ Falling}$ | 0 | 90 | 160 | mV | |
| | Sleep Mode Exit Hysteresis | 2.3 V ≤ V _{BAT} ≤ V _{OREG} | | 40 | | mV | |
| V_{SLP_EXIT} | Deglitch Time for V_{BUS} Rising Above V_{SLP} + V_{SLP_EXIT} | Rising Voltage | | 30 | | ms | |
| Power Sw | itches (see Figure 3) | | | | | | |
| | Q3 On Resistance (VBUS to PMID1) | IBUS _(LIMIT) ≥ 500 mA | | 210 | 300 | | |
| R _{DS(ON)} | Q1 On Resistance (PMID1 to SW1) | | | 110 | 225 | | |
| | Q2 On Resistance (SW1 to GND) | | | 130 | 225 | | |
| | Q4 On Resistance (VIN to PMID2) | | | 160 | 225 | mΩ | |
| | Q5 On Resistance (PMID2 to SW2) | | | 110 | 225 | | |
| | Q6 On Resistance (SW2 to GND) | | | 190 | 350 | | |
| Charger F | WM Modulator | | | | | | |
| f _{SW} | Oscillator Frequency | | 2.7 | 3.0 | 3.3 | MHz | |
| D _{MAX} | Maximum Duty Cycle | | | | 100 | % | |
| D _{MIN} | Minimum Duty Cycle | | | 0 | | % | |
| I _{SYNC} | Synchronous to Non- Synchronous Current Threshold ⁽³⁾ | Low-Side MOSFET Cycle-by-Cycle Current Limit | | -120 | | mA | |
| Boost Mo | de Operation (OPA_MODE = 1, | HZ1 = 0) | | 1 | | | |
| | | 2.5 V < V _{BAT} < 4.5 V, 0-200 mA Load | 4.80 | 5.05 | 5.17 | | |
| V _{BOOST} | Boost Output Voltage at VBUS | 2.7 V < V _{BAT} < 4.5 V, 0-300 mA Load | 4.77 | 5.05 | 5.17 | V | |
| BAT(BOOST) | Boost Mode Quiescent Current | PFM Mode, $V_{IN} = 3.6 \text{ V}$, $I_{OUT} = 0$ | | 300 | 400 | μA | |
| ILIMPK(BST) | Q2-Peak Current Limit | | 1160 | 1380 | 1550 | mA | |
| V _{BAT(MAX)} | Maximum Battery Input for Boost Operation | V _{BAT} Rising | 4.7 | / | | V | |
| . , | Hysteresis | V _{BAT} Falling | | 125 | | mV | |
| UVLO _{BST} | Minimum Battery Voltage for | While Boost Active | | 2.42 | | V | |
| OVLOBSI | Boost Operation | To Start Boost Regulator | | 2.58 | 2.70 | v | |
| VBUS, VI | Load Resistance | | | | | | |
| R _{VBUS} | VBUS to GND Resistance | Normal Operation | 500 | 1000 | 1500 | Ω | |
| INVBUS | | V _{BUS} Validation | 50 | 110 | 175 | Ω | |
| D | VIN to GND Resistance | Normal Operation | 500 | 1000 | 1500 | Ω | |
| R _{VIN} | VIIN IO GIND RESISIANCE | V _{IN} Validation | 50 | 110 | 175 | Ω | |

Continued on the following page ...

Electrical Specifications (Continued)

Unless otherwise specified: circuit of Figure 1, recommended operating temperature range for T_J and T_A , V_{BUS} or $V_{IN} = 5.0$ V, HZ1, HZ2, OPA_MODE = 0, (Charger Mode). SCL, SDA, OTG = 0 or 1.8 V. Typical values are for $T_J = 25^{\circ}$ C.

| Symbol | Parameter | Conditions | Min. | Тур. | Max. | Units | |
|----------------------|---|--|------|------|------|-------|--|
| Protection | and Timers | | • | I | | • | |
| VDUE | VBUS Over-Voltage Shutdown | V _{BUS} Rising | 6.12 | 6.31 | 6.50 | V | |
| VBUSOVP | Hysteresis | V _{BUS} Falling | | 100 | | mV | |
| \/INI | VIN Over-Voltage Shutdown V _{IN} Rising 9.5 10.0 | | 10.0 | 10.5 | V | | |
| VINOVP | Hysteresis | Hysteresis V _{IN} Falling 100 | | 100 | | mV | |
| N/ | Battery Short-Circuit Threshold | V _{BAT} Rising | 2.00 | 2.05 | 2.10 | | |
| V _{SHORT} | Hysteresis V _{BAT} Falling | | | 100 | | V | |
| I _{SHORT} | Short-Circuit Current | V _{BAT} < V _{SHORT} | 30 | 40 | 50 | mA | |
| – | Thermal Shutdown Threshold ⁽⁴⁾ | T _J Rising | | 165 | | °C | |
| T _{SHUTDWN} | Hysteresis ⁽⁴⁾ | T _J Falling | 6 | 10 | | | |
| T_{CF} | Thermal Regulation Threshold ⁽⁴⁾ | Charge Current Reduction Begins | | 120 | | °C | |
| t _{INT} | Detection Interval | | | 2.1 | | S | |
| t _{32SEC} | 32-Second Timer ⁽⁵⁾ | 32-Second Mode | 21.0 | | 31.5 | S | |
| t _{15MIN} | 15-Minute Timer | 15-Minute Mode | 12.0 | 13.5 | 15.0 | min | |
| Δt_{LF} | Low Frequency Timer Accuracy | Charger Inactive | -25 | | 25 | % | |

Notes:

2. Refers to negative inductor current. At lower battery charging current, of about 20 mA, non-synchronous switching operation commences.

3. Q2 and Q6 always turn on for »60 ns and then turn off if the current is below I_{SYNC}.

4. Guaranteed by design.

5. This tolerance applies to all timers on the IC, including soft-start and deglitching timers.

I²C Timing Specifications

Guaranteed by design.

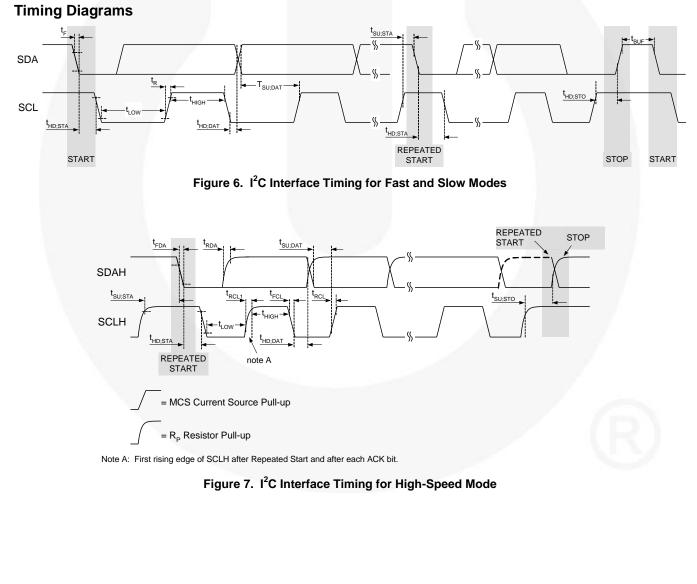
| Symbol | Parameter | Conditions | Min. | Тур. | Max. | Uni | |
|---------------------------------------|--|---|------|-------------------|------|-----|--|
| | | Standard Mode | | | 100 | | |
| | | Fast Mode | | | 400 | | |
| f _{SCL} | SCL Clock Frequency | High-Speed Mode, C _B ≤ 100 pF | | | 3400 | kHz | |
| | | High-Speed Mode, C _B ≤ 400 pF | | | 1700 | | |
| | Bus-Free Time between STOP | Standard Mode | | 4.7 | | | |
| t _{BUF} | and START Conditions | Fast Mode | | 1.3 | | μs | |
| | | Standard Mode | | 4 | | μs | |
| t _{HD;STA} | START or Repeated START Hold Time | Fast Mode | | 600 | | ns | |
| | | High-Speed Mode | | 160 | | ns | |
| | | Standard Mode | | 4.7 | | μS | |
| | | Fast Mode | | 1.3 | | μS | |
| t _{LOW} | SCL LOW Period | High-Speed Mode, C _B ≤ 100 pF | | 160 | | ns | |
| | | High-Speed Mode, $C_B \le 400 \text{ pF}$ | | 320 | | ns | |
| | / | Standard Mode | | 4 | | μS | |
| | | Fast Mode | | 600 | | ns | |
| t _{HIGH} | SCL HIGH Period | High-Speed Mode, $C_B \le 100 \text{ pF}$ | | 60 | | ns | |
| | | High-Speed Mode, $C_B \leq 400 \text{ pF}$ | | 120 | | ns | |
| | | Standard Mode | | 4.7 | | με | |
| t _{SU:STA} | STA Repeated START Setup Time | Fast Mode | | 600 | | ns | |
| | High-Speed Mode | | 160 | | ns | | |
| tsu:dat | Data Setup Time | Standard Mode | | 250 | | | |
| | | Fast Mode | | 100 | | ns | |
| COUDAT | | High-Speed Mode | | 100 | | | |
| | | Standard Mode | 0 | 10 | 3.45 | μ | |
| | | Fast Mode | 0 | | 900 | ns | |
| t _{HD;DAT} | Data Hold Time | High-Speed Mode, $C_B \le 100 \text{ pF}$ | 0 | | 70 | ns | |
| | | High-Speed Mode, $C_B \le 100 \text{ pf}$ | 0 | | 150 | ns | |
| | | Standard Mode | |).1С _в | 1000 | 110 | |
| | | Fast Mode | |).1Св | 300 | | |
| t _{RCL} | SCL Rise Time | High-Speed Mode, $C_B \le 100 \text{ pF}$ | 20+0 | 10 | 80 | ns | |
| | | High-Speed Mode, $C_B \le 400 \text{ pF}$ | | 20 | 160 | | |
| | | Standard Mode | 20+(|).1C _B | 300 | | |
| | | Fast Mode | |).1C _B | 300 | | |
| t _{FCL} | SCL Fall Time | High-Speed Mode, $C_B < 100 \text{ pF}$ | 2010 | 10 10 | 40 | ns | |
| | | High-Speed Mode, $C_B \le 400 \text{ pF}$ | | 20 | 80 | - | |
| | | Standard Mode | 20⊥(| _ | 1000 | | |
| | SDA Rise Time | Standard Mode 20+0.1C _B Fast Mode 20+0.1C _B | | | 300 | | |
| t _{RDA} t _{RCL1} | Rise Time of SCL after a Repeated START Condition | High-Speed Mode, $C_B \le 100 \text{ pF}$ | 20+0 | 10 | 80 | ns | |
| | and after ACK Bit | Γ ingri opeen mode, OB \leq 100 pr | | 10 | 00 | - | |

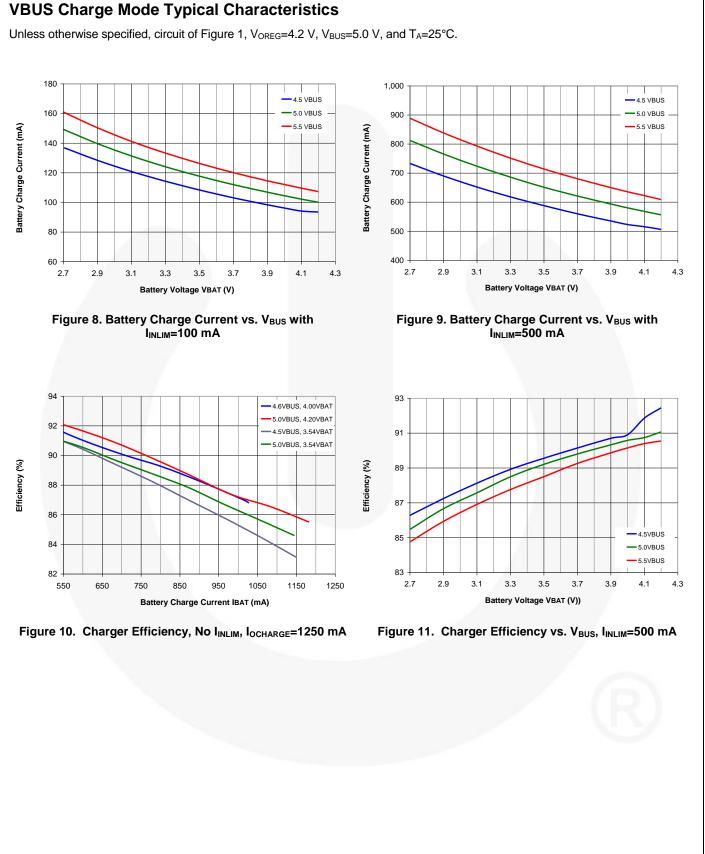
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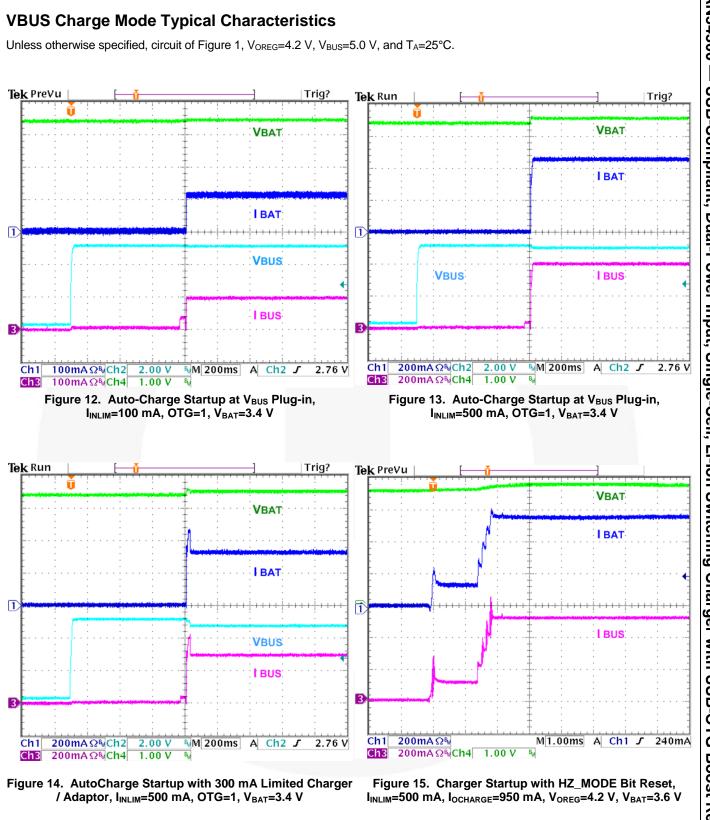
I²C Timing Specifications

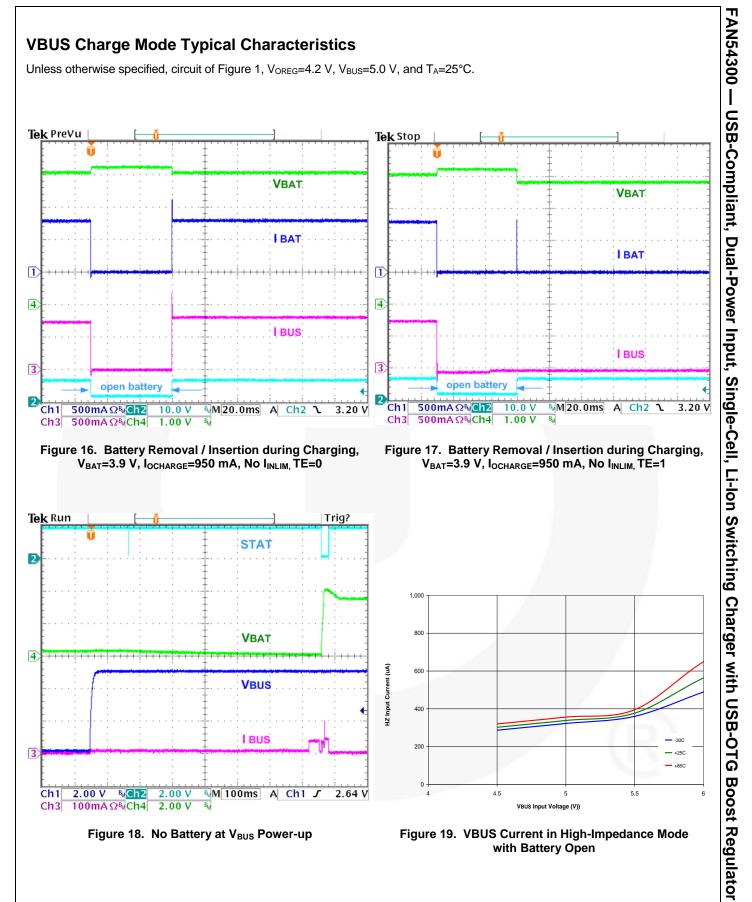
Guaranteed by design.

| Symbol | Parameter | Conditions | | Тур. | Max. | Unit |
|---------------------|--|--|----------------------|------|------|------|
| | Standard Mode | 20+0 |).1C _B | 300 | | |
| | SDA Fall Time | Fast Mode | 20+0.1C _B | | 300 | |
| ^L FDA | t _{FDA} SDA Fall Time | High-Speed Mode, $C_B \leq 100 \text{ pF}$ | | 10 | 80 | ns |
| | High-Speed Mode, $C_B \leq 400 \text{ pF}$ | | 20 | 160 | | |
| | | Standard Mode | | 4 | | μS |
| t _{SU;STO} | Stop Condition Setup Time | Fast Mode | | 600 | | ns |
| | | High-Speed Mode | | 160 | | ns |
| CB | Capacitive Load for SDA, SCL | | | | 400 | pF |



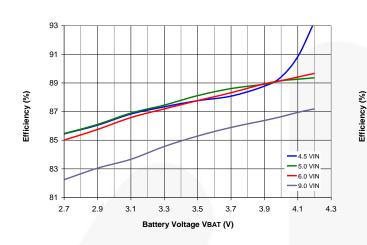






VIN Charger Characteristics

Unless otherwise specified, circuit of Figure 1, V_{OREG} = 4.2 V, V_{IN} = 5.0 V, and T_A =25°C.



91 88 85 82 4.5 VIN 5.0 VIN 79 6.0 VIN 9.0 VIN 76 2.7 2.9 3.1 3.3 3.5 3.7 3.9 4.1 4.3 Battery Voltage VBAT (V)

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Figure 20. Charger Efficiency, Iocharge=950 mA

Figure 21. Charger Efficiency, Iocharge=1550 mA

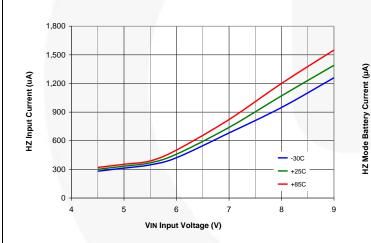


Figure 22. V_{IN} Current in High-Impedance Mode, V_{BAT}=3.6 V

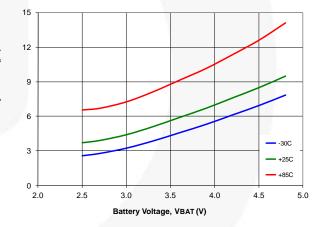
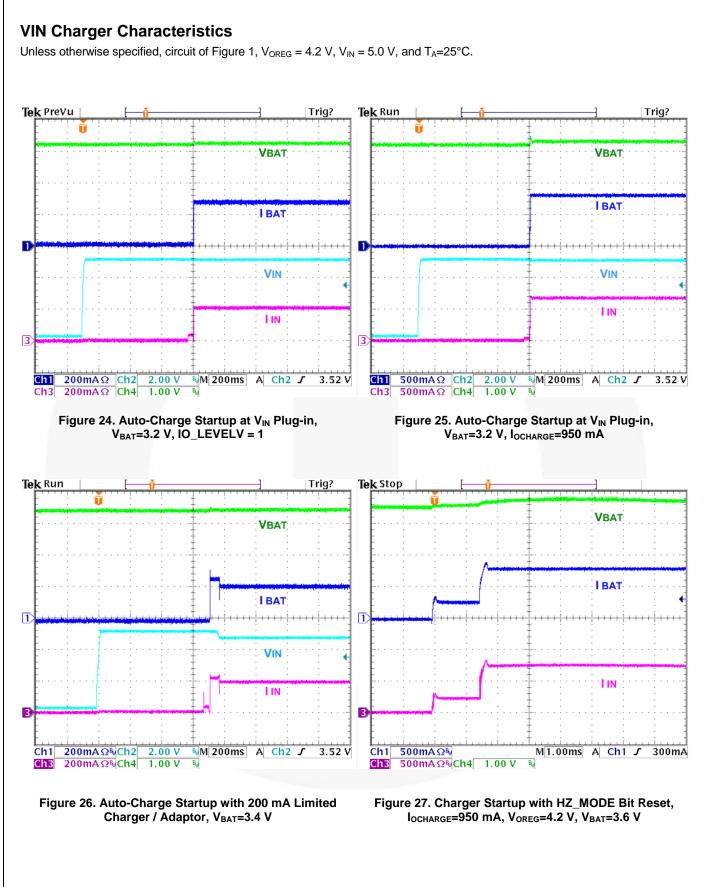
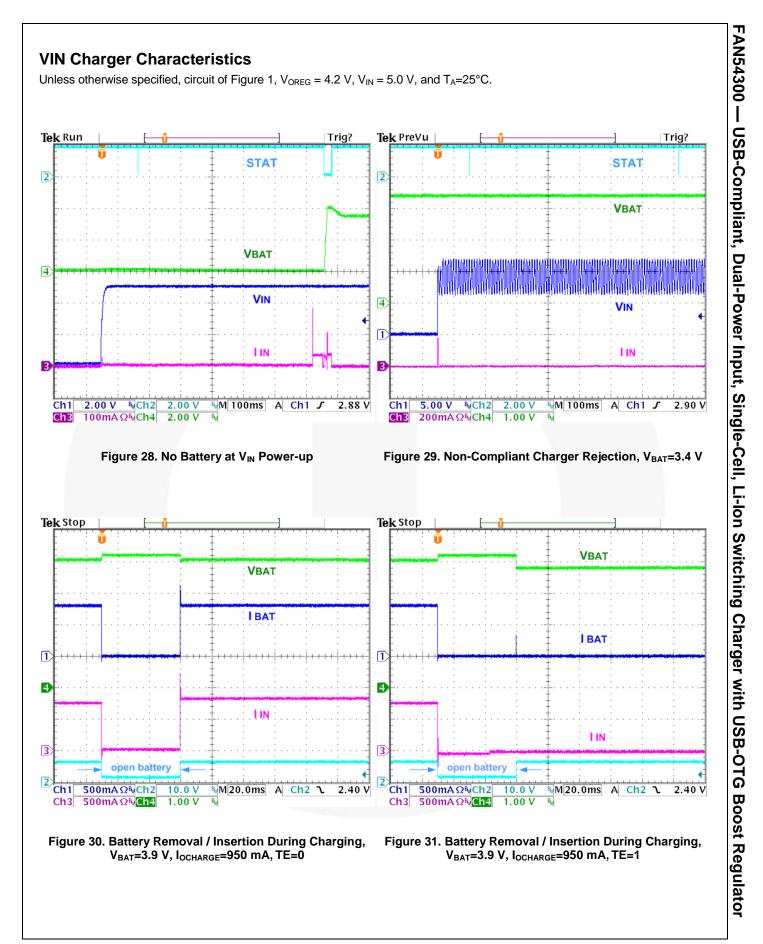
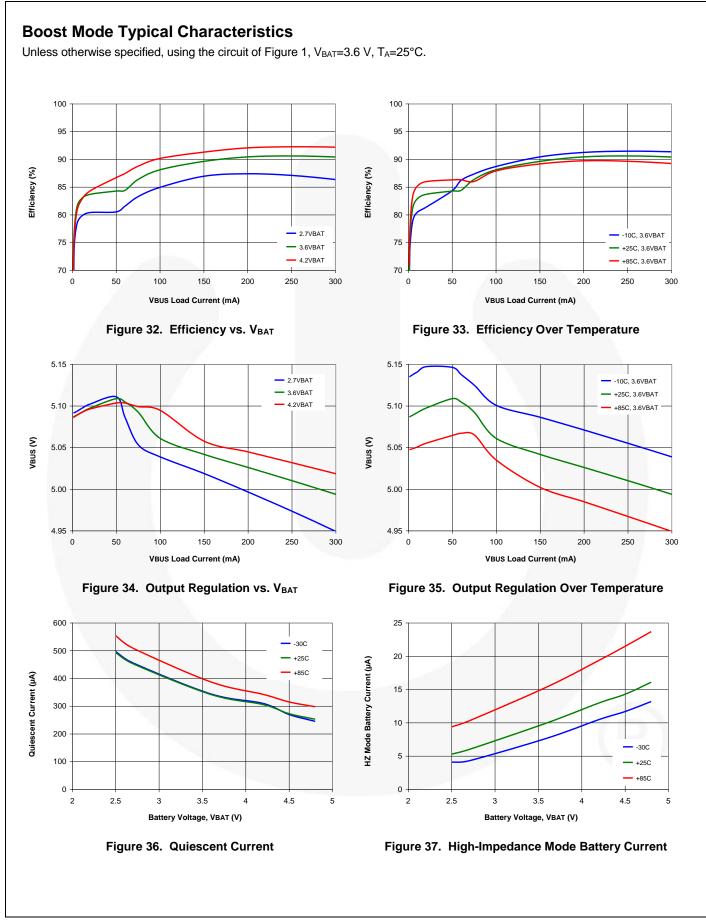
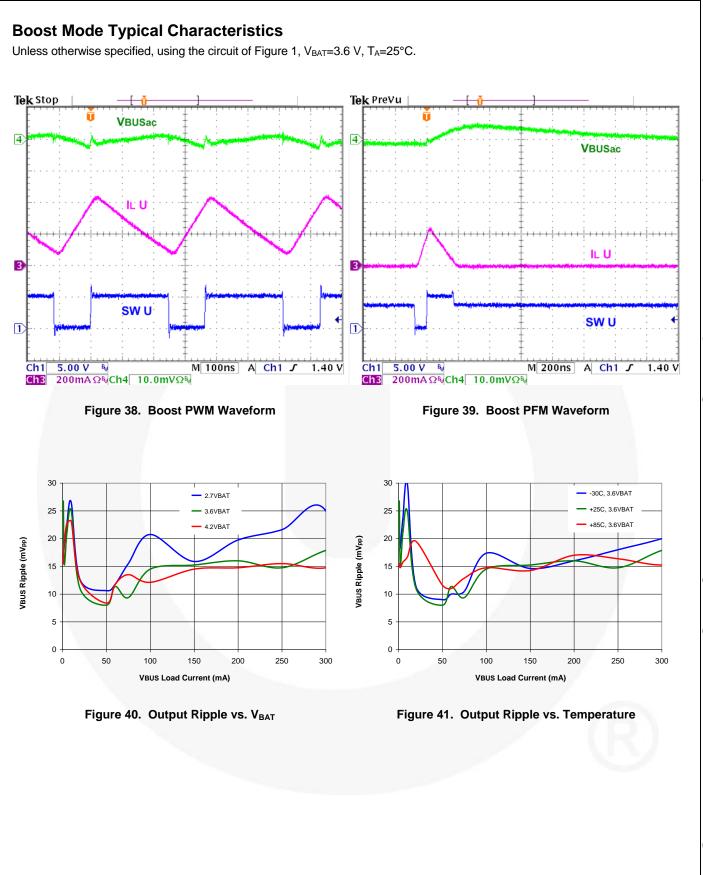


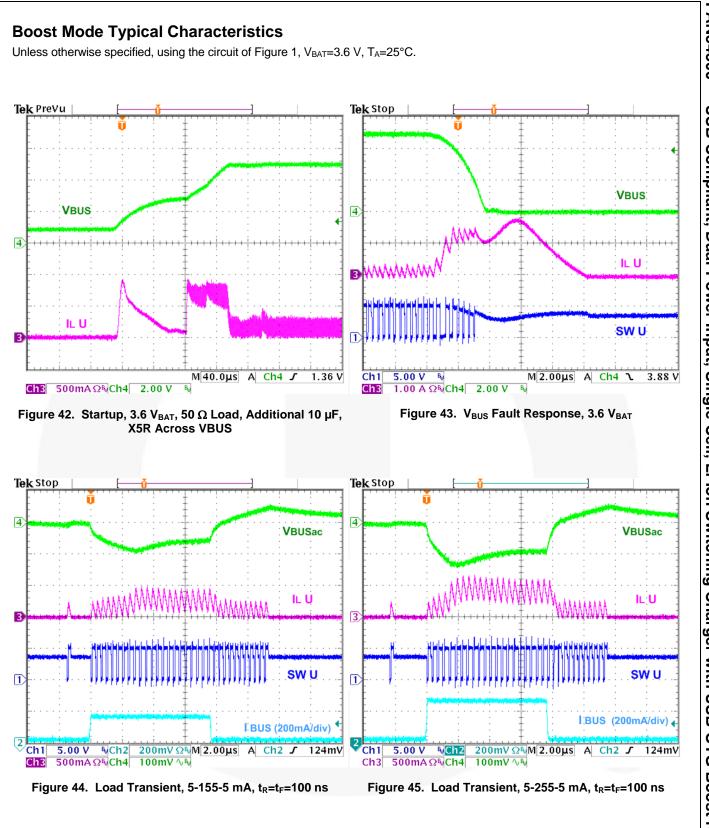
Figure 23. Battery Current in High-Impedance Mode, VBUS=Open, V_{IN}=Open











Circuit Description / Overview

When charging batteries with a current-limited input source, such as USB, a switching charger's high efficiency over a wide range of output voltages minimizes charging time.

The FAN54300 combines two highly integrated synchronous buck regulators for charging from two separate power sources. The IC also includes a synchronous boost regulator, which can supply 5 V to USB On-The-Go (OTG) peripherals. The regulator employs synchronous rectification for both the charger and boost regulators to maintain high efficiency over a wide range of battery voltages and charge states.

In addition to its USB (VBUS) input, the FAN54300 allows a second power source (VIN) to be used for charging. This input source is typically a "wall wart" and can be up to 9.5 V input.

The FAN54300 has three operating modes:

Charge Mode:

Charges a single-cell Li-lon or Li-polymer battery.

Boost Mode:

Provides 5 V power to USB-OTG with an integrated synchronous rectification boost regulator using the battery as input.

High-Impedance Mode:

Both the boost and charging circuits are off in this mode. Current flow from PWRIN (the charging power source) to the battery, or from the battery to PWRIN, are blocked in this mode. This mode consumes very little current from PWRIN or the battery.

When the IC is charging the battery from VIN, the boost regulator may be simultaneously enabled to supply 5 V for OTG peripherals.

Charge Mode

In Charge Mode, FAN54300 employs five regulation loops:

- 1. VBUS input current: Limits the amount of current drawn from VBUS. This current is sensed internally and can be programmed through the I²C interface
- 2. Charging current: Limits the maximum charging current. This current is sensed using an external R_{SENSE} resistor.
- 3. Charge voltage: The regulator is restricted from exceeding this voltage. As the internal battery voltage rises, the battery's internal impedance and R_{SENSE} works in conjunction with the charge voltage regulation to decrease the amount of current flowing to the battery. Battery charging is completed when the voltage across R_{SENSE} drops below the I_{TERM} threshold.
- Temperature: If the IC's junction temperature reaches 120°C, charge current is continuously reduced until the IC's temperature stabilizes at 120°C.
- An additional loop limits the amount of drop on VBUS or VIN to a programmable voltage (V_{SP}) to accommodate current-limited wall chargers.

Input Source Selection

The FAN54300 selects the power source (PWRIN) for charging according to the following criteria.

Table 3. PWRIN: Charging Power Input Source Selection

| V _{IN} | V _{BUS} | PWRIN |
|-----------------|------------------|------------------|
| VALID | INVALID | V _{IN} |
| INVALID | VALID | V _{BUS} |
| VALID | VALID | V _{IN} |

If charging is in progress with V_{BUS} and V_{IN} becomes valid, charging from VBUS stops and charging continues from V_{IN} . Charging stops if HZ_VIN is set when V_{IN} becomes valid while charging with V_{BUS} .

If VIN and VBUS are both connected and t_{15MIN} expires, both CE# bits are set. To reinitiate t_{15MIN} charging (autocharge) with a weak battery, both power sources must be unplugged, then a valid power source plugged in. If only one of the two connected sources are removed then connected with a weak battery, both CE# bits remain set.

Fault Reporting and Register Reset

All faults that occur during charging or boost are reported only in the STATUS register (R0) associated with the active charging source at the time of the fault. Any register reset that occurs due to t_{32SEC} overflow resets only the associated with the active charging source.

For example: Assume the IC is charging in 32-Second Mode with V_{IN} as a source. The processor stops setting TMR_RST, so t_{32SEC} expires. The IC then resets only the _V registers and goes into 15-Minute Mode charging with V_{IN}. A timer fault is enunciated, but reported in the CONTROLO_V register. CONTROLO_U is unaffected by this event. When the t_{15MIN} timer expires, the IC sets the CE#_V bit, but leaves the CE#_U bit unchanged.

Battery Charging Curve

If the battery voltage is below V_{SHORT}, a linear current source "pre-charges" the battery until V_{BAT} reaches V_{SHORT}. The PWM charging circuits are then started and the battery is charged with a constant current if sufficient input power is available. The current slew rate is limited to prevent overshoot.

The FAN54300 is designed to work with a current-limited input source at PWRIN. During the current regulation phase of charging, PWRIN current limitations or the programmed charging current limit the amount of current available to charge the battery and power the system. The effect of input power limitations on I_{CHARGE} can be seen in Figure 47.

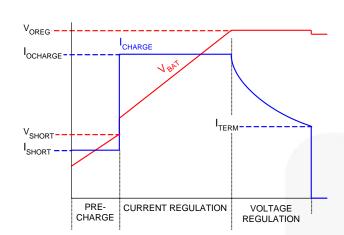


Figure 46. Charge Curve when PWRIN Limitations Don't Limit I_{CHARGE}

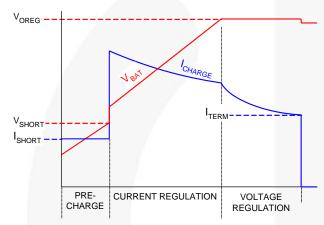


Figure 47. Charge Curve when PWRIN Limits I_{CHARGE}

PWRIN limitations are controlled either by:

- IBUSLIM: These bits set the maximum amount of current that the charger draws from VBUS; OR
- SP CHARGER: For power-limited chargers. the FAN54300 limits current draw when the charging source drops to the voltage programmed by the SP_CHARGER bits. This allows "travel adapters" to be accommodated without host software overhead. The SP_CHARGER control loop applies to both VIN and VBUS.

Assuming VOREG is programmed to the cell's fully charged "float" voltage, the current the battery accepts with the PWM regulator limiting its output (sensed at VBAT) to VOREG declines and the charger enters the voltage regulation phase of charging. When the current declines to the programmed ITERM value, the charge cycle is complete. Charge current termination can be disabled by resetting the TE bit.

Charger Programmability

Throughout this document, any parameter that ends in "U" applies when charging from $V_{\mbox{\scriptsize BUS}}$ and any parameter ending in "V" applies when charging from VIN. Parameters set with slave address D6 are applied when charging from V_{BUS}. Parameters set with slave address D4 are applied when charging from VIN.

The following charging and input power control parameters can be programmed by the host through I^2C .

Table 4. Programmable Charging Parameters

| Parameter | Charging Source | Name | Register |
|------------------------------------|--------------------|---------|-----------|
| Output Voltage Regulation | Either | OREG | REG2[7:2] |
| Battery Charging | V _{BUS} | ICHGU | REG4[6:4] |
| Current Limit | V _{IN} | ICHGV | REG4[6:3] |
| Input Current Limit | V _{BUS} | IBUSLIM | REG1[7:6] |
| Charge Termination Limit | Either | ITERM | REG4[2:0] |
| Special Charger Minimum Voltage | Either | VSP | REG5[2:0] |

The charger output or "float" voltage can be programmed by the OREG bits from 3.5 V to 4.44 V in 20 mV increments.

Table 5. OREG Bits (REG2 [7:2]) vs. Charger Vout (V_{OREG}) Float Voltage

| (OKLO) - | | | | | - |
|-----------|-----|-------|---------|-----|-------|
| Decimal | Hex | VOREG | Decimal | Hex | VOREG |
| 0 | 00 | 3.50 | 32 | 20 | 4.14 |
| 1 | 01 | 3.52 | 33 | 21 | 4.16 |
| 2 | 02 | 3.54 | 34 | 22 | 4.18 |
| 3 | 03 | 3.56 | 35 | 23 | 4.20 |
| 4 | 04 | 3.58 | 36 | 24 | 4.22 |
| 5 | 05 | 3.60 | 37 | 25 | 4.24 |
| 6 | 06 | 3.62 | 38 | 26 | 4.26 |
| 7 | 07 | 3.64 | 39 | 27 | 4.28 |
| 8 | 08 | 3.66 | 40 | 28 | 4.30 |
| 9 | 09 | 3.68 | 41 | 29 | 4.32 |
| 10 | 0A | 3.70 | 42 | 2A | 4.34 |
| 11 | 0B | 3.72 | 43 | 2B | 4.36 |
| 12 | 0C | 3.74 | 44 | 2C | 4.38 |
| 13 | 0D | 3.76 | 45 | 2D | 4.40 |
| 14 | 0E | 3.78 | 46 | 2E | 4.42 |
| 15 | 0F | 3.80 | 47 | 2F | 4.44 |
| 16 | 10 | 3.82 | 48 | 30 | 4.44 |
| 17 | 11 | 3.84 | 49 | 31 | 4.44 |
| 18 | 12 | 3.86 | 50 | 32 | 4.44 |
| 19 | 13 | 3.88 | 51 | 33 | 4.44 |
| 20 | 14 | 3.90 | 52 | 34 | 4.44 |
| 21 | 15 | 3.92 | 53 | 35 | 4.44 |
| 22 | 16 | 3.94 | 54 | 36 | 4.44 |
| 23 | 17 | 3.96 | 55 | 37 | 4.44 |
| 24 | 18 | 3.98 | 56 | 38 | 4.44 |
| 25 | 19 | 4.00 | 57 | 39 | 4.44 |
| 26 | 1A | 4.02 | 58 | ЗA | 4.44 |
| 27 | 1B | 4.04 | 59 | 3B | 4.44 |
| 28 | 1C | 4.06 | 60 | 3C | 4.44 |
| 29 | 1D | 4.08 | 61 | 3D | 4.44 |
| 30 | 1E | 4.10 | 62 | 3E | 4.44 |
| 31 | 1F | 4.12 | 63 | 3F | 4.44 |
| Note: | | | | | |

Note:

6. All register default settings are noted by **bold typeface**.

(see Figure 48)

Charge Initiation

A new charge cycle begins when one of the following occurs:

- The battery voltage falls below V_{OREG} V_{RCH}
- A power source is connected (PWRIN POR) and battery voltage is below the weak-battery threshold (V_{LOWV}).
- CE# and HZ_MODE are both cleared, after having been set, and a power source is connected.

Charge Current Limit

The default charge current is limited by the IOLEVEL bit (REG5[5]). When this bit is set (default), charge current is limited to 325 mA (22.1 mV across R_{SENSE}) and the ICHG bits are ignored. Resetting IOLEVEL allows the ICHG bits to control the battery charge current limit.

Any attempt to write a value higher than 10 (0AH) results in a value of 10 (0AH) written to the ICHGV bits (see Table 24).

Charge Termination Current Limit

Current charge termination is enabled when TE (REG1[3]) = 1. The current level is control by the ITERM bits (REG4[2:0].

PWM Controller in Charge Mode

The IC uses a current-mode PWM controller to regulate the output voltage and battery charge currents. A cycle-by-cycle current limit of nominally 2.3 A, sensed through Q1, is used to terminate t_{ON} . The synchronous rectifier, Q2, also has a current limit that turns off Q2 at 160mA to prevent current flow from the battery.

When the charge current drops below ~20 mA; the IC runs in Asynchronous Mode, which prevents reverse current from pumping up the input source.

Safety Timer (see Figure 52)

At the beginning of the charging process, the IC starts the 15-minute timer (t_{15MIN}). When this timer expires, charging is terminated and the CE# bit is set. Writing to any register through I²C stops the t_{15MIN} timer, which, in turn, starts a 32-second timer (t_{32SEC}). Setting the TMR_RST bit (REG0[1]) resets the t_{32SEC} timer. If the t_{32SEC} timer times out, all registers (except SAFETY) are set to their default values, a Timer Fault (110) is reported in the fault register, and charging resumes using the default values with the t_{15MIN} timer running.

Since there is only one t_{32SEC} timer on the IC, writing to either TMR_RST bit in either CONTROL0_U or CONTROL0_V resets the timer. The t_{32SEC} timer starts with an I²C WRITE to either slave address. Timer faults are reported in both U and V registers. A t_{32SEC} fault resets U and V registers 1 – 5.

Normally, charging is controlled by the host with the t_{32SEC} timer running to ensure that the host is active. Charging with the t_{15MIN} timer running is used for charging that is unattended by the host, which would occur when V_{BAT} is insufficient to power the host processor. If the 15-minute timer expires, the IC turns off the charger and indicates a timer fault (110) on the FAULT bits (REG0[2:0]). This prevents overcharge if the host fails to reset the t_{32SEC} timer. The CE# bit is set in the registers where the power sources are connected. For example, if VIN and VBUS are both connected when the t_{15MIN} timer expires, CE#_V and CE_U are both set.

Reset Bit

Setting the RESET bit (Reg4[7]) resets all registers for the slave address used to set the RESET bit. When the RESET bit is set, the t_{32SEC} timer is reset and stopped, charging stops and the IC goes to Charge Configuration Mode *(see Figure 50)*. If V_{BAT} < V_{OREG}, charging begins in 15-Minute Mode 262 ms after the RESET bit is set.

PWRIN Validation, Notification, and Non-Compliant Power Source Rejection

Whenever either VBUS_CON or VIN_CON bits have been set, the STAT pin pulses to notify the host processor of a change in status on the input power supply.

Before attempting to charge, the IC attempts to validate its input source by loading the appropriate source with 110 Ω to ensure that the source stays between 4.4 V and VIN_{OVP} for 32 ms. If the input source fails validation, STAT enunciates a fault and the fault bits are set according to the condition of the input source (OVP or poor input source). The PWRIN validation sequence always occurs before charging is initiated or re-initiated (for example, after a PWRIN OVP fault, a V_{RCH} recharge initiation, or resetting the HZ bit). The 32 ms validation time ensures that unfiltered 50/60 Hz chargers and other non-compliant chargers are rejected.

2.5 V Regulator Operation

When the VIN_CON bit is set, indicating that the VIN power source has been plugged in, the V2V5 regulator is enabled.

USB-Friendly Boot Sequence

At PWRIN POR, when the battery voltage is above the weak-battery threshold (V_{LOW}), the IC goes into Charge Configuration Mode unless the t_{32SEC} timer is enabled by an I²C write. In that case, the IC begins to charge with the existing register settings.

If V_{BAT} < V_{LOW}, the IC goes into Charge Configuration Mode if the t_{32SEC} timer is not enabled. If V_{BAT} < V_{OREG}, the registers reset and charging begins in 15-Minute Mode. During 15-Minute Mode, the charger uses an input current limit controlled by the OTG pin when charging from VBUS (100mA if OTG is LOW and 500mA if OTG is HIGH).

Even if charging from VIN, the charging current is limited to 325 mA (22.14 mV across 68m Ω) after the registers are reset. This feature can revive a cell whose voltage is too low for reliable host operation until the battery has sufficient charge for the host to boot up and set charge parameters. Charging continues in the absence of host communication even after the battery has reached V_{OREG}, with a default value of 3.54 V, and the charger remains active until t_{15MIN} times out.

Once the host processor begins writing to the IC, charging parameters are set by the host, which must continually reset the t_{32SEC} timer to continue charging using programmed charging parameters. If t_{32SEC} times out, the register defaults are loaded, the FAULT bits are set to 110, STAT is pulsed, and charging continues with default charge parameters.

At PWRIN POR, if V_{BAT} < V_{LOW} and HZ or CE# were set previously, the IC goes into HZ state, which causes the registers to reset, clearing the HZ and CE# bits when t_{32SEC} expires and beginning t_{15MIN} charging unless the host processor sets the TMR_RST bit.

VBUS Current Limiting

To minimize charging time without overloading VBUS's current limitations, the IC's VBUS current limit can be programmed with the IBUSLIM bits (REG1[7:6]).

Operational Flow Charts

The OTG pin establishes the VBUS current limit during 15-Minute Mode charging.

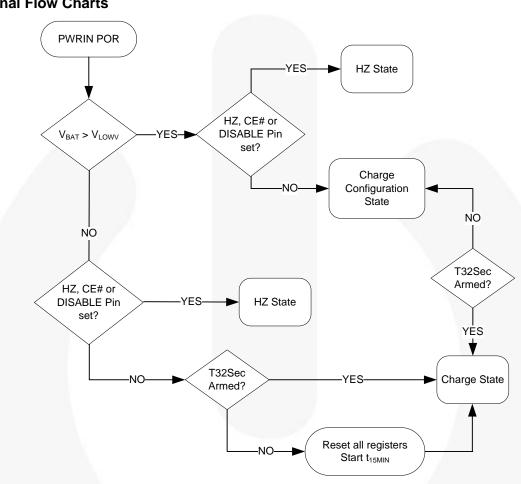
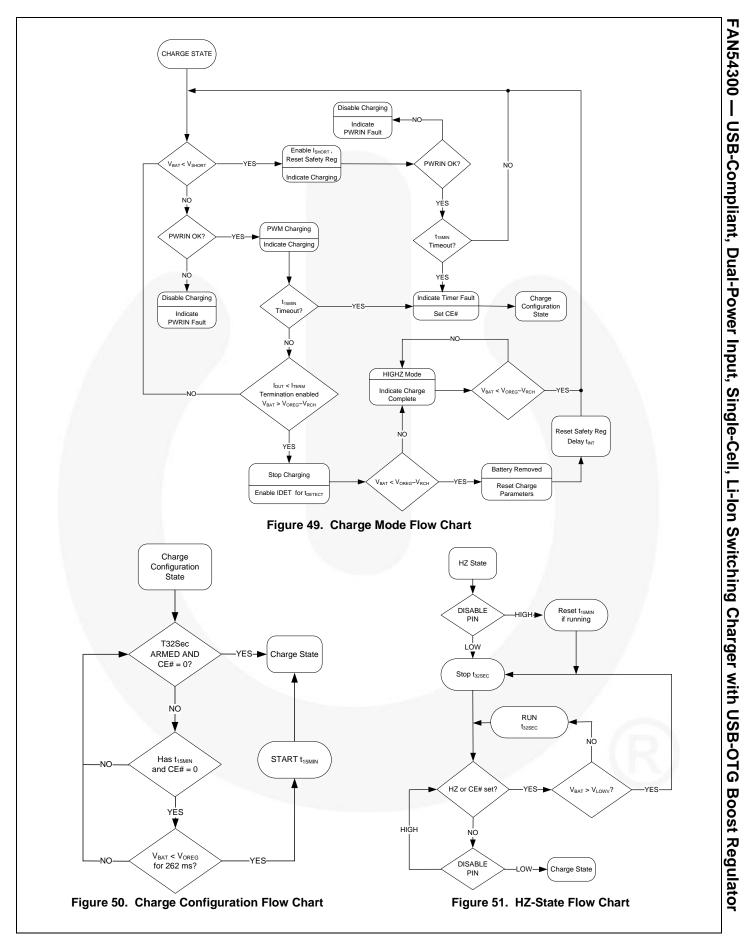


Figure 48. Charger PWRIN POR Flow Chart



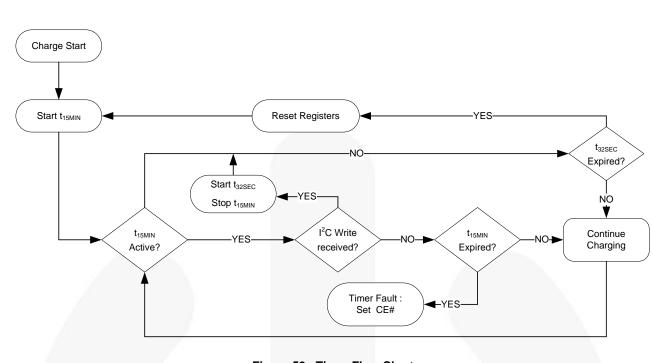


Figure 52. Timer Flow Chart

Special Charger

The IC limits input current in case a current-limited charger is supplying V_{BUS} or $V_{\text{IN}}.$ The IC slowly increases the charging current until either:

- I_{BUSLIM} or I_{CHARGE} is reached; or
- V_{PWRIN} = V_{SP} where V_{PWRIN} is the selected input power source (see Table 4).

If V_{PWRIN} collapses to V_{SP} when current is ramping up, the IC charges with an input current that keeps V_{PWRIN} = V_{SP}. When the V_{SP} control loop is limiting the charge current, the SP bit (REG5[4]) is set. V_{SP} default value is 4.53 V, but it can be programmed by REG5[2:0].

Safety Settings

A SAFETY register (REG6) prevents the values in OREG (REG2[7:2]) and ICHG (REG4[6:3]) from exceeding the values of the VSAFE and ISAFE values.

After V_{BAT} rises above V_{SHORT}, the SAFETY register is loaded with its default value and may be written only before any other register is written. After writing to any other register, the SAFETY register is locked until V_{BAT} falls below V_{SHORT}. The SAFETY register is reset whenever the SRST pin is LOW.

ISAFE and VSAFE establish values that limit the maximum values of ICHG and OREG used by the control logic. If the host attempts to write a value higher than VSAFE or ISAFE to OREG or ICHG, respectively; the VSAFE, ISAFE value appears as the OREG, ICHG register value, respectively.

For the SAFETY_U register, any attempt to write an ISAFE value higher than 10 (0AH) results in a value of 10 being written to the ISAFE bits. See Table 21 for VSAFE values and Table 20 and Table 26 for ISAFE values.

Thermal Regulation and Protection

When the IC's junction temperature reaches T_{CF} (about 120°C) the charger reduces its output current to prevent overheating. If the temperature continues to increase, the current is reduced to 0 when the junction is 10°C above T_{CF} . If the temperature increases beyond $T_{SHUTDOWN}$, charging is suspended, the FAULT bits are set to 101, and SAT is pulsed. In Suspend Mode, all timers stop and the state of the IC's logic is preserved. Charging resumes after the die cools to about 10°C below $T_{SHUTDOWN}$.

Charge Mode Input Supply Protection

Sleep Mode

When V_{BUS} and V_{IN} are both below V_{BAT} , the IC enters Sleep Mode. To prevent the battery from discharging into VBUS, reverse current is prevented by body switching Q1 when PMID1 falls below V_{BAT} .

Similarly, when V_{IN} falls below $V_{\text{BAT}},\ Q4$ turns off, blocking battery current flow into VIN.

Input Supply Low-Voltage Detection

The IC continuously monitors V_{PWRIN} during charging. If the input voltage for the active charging source falls below 3.7 V, the IC terminates charging, pulses the STAT pin, sets STAT bits to 11, and sets the FAULT bits to 011 for the appropriate input source.

If the power source recovers above the V_{IN(MIN)} rising threshold after timer t_{INT} (about two seconds), the charging process is repeated. This prevents the USB power bus from collapsing or oscillating when the IC is connected to a suspended USB port or an OTG device with low current capability.

Input Over-Voltage Detection

When V_{BUS} exceeds its OVP threshold, the IC:

- 1. Turns off Q3;
- 2. Suspends charging from V_{BUS}; and
- 3. Sets the FAULTU bits to 001, STATU bits to 11, and pulses the STAT pin.

When V_{BUS} falls to about 150 mV below VBUS_{OVP}, the fault is cleared, and charging resumes after V_{BUS} is revalidated.

If VIN exceeds its OVP threshold, the IC:

- 1. Turns off Q4;
- 2. Suspends charging from V_{IN} ; and
- 3. Sets the FAULTV bits to 001, STATV bits to 11, and pulses the STAT pin.

Charge Mode Battery Detection & Protection

VBAT Over-Voltage Protection

The OREG voltage regulation loop prevents V_{BAT} from overshooting the OREG voltage by more than 50 mV when the battery is removed. When the PWM charger is running with no battery, the TE bit is not set, and a battery is inserted that's charged to a voltage higher than V_{OREG} ; PWM pulses stop. If no further pulses occur for 30 ms, the IC sets the FAULT bits to 100, STAT bits to 11, and pulses the STAT pin.

Battery Detection During Charging

The IC can detect presence, absence, or removal of a battery. During normal charging, once V_{BAT} is greater than $V_{OREG}-V_{RCH}$ and the termination charge current is detected; the IC terminates charging and sets the STAT bits to 10. It then turns on a discharge current, $I_{DETECT},$ for t_{DETECT} . If V_{BAT} is still above $V_{OREG}-V_{RCH}$, the battery is present and the IC sets the FAULT bits to 000. If V_{BAT} is below $V_{OREG}-V_{RCH}$, the battery is absent and the IC:

- 1. Sets the registers to their default values;
- 2. Sets the FAULT bits to 111; and
- 3. Resumes charging with default values after delay t_{INT}.

Battery Detection During Power-up

At PWRIN POR, if the charger is in 15-Minute Mode (no I^2C writes from the host detected), the IC starts a 32 ms timer when V_{BAT} crosses V_{SHORT} and starts PWM charging. If V_{BAT} exceeds 3.7 V within a 32 ms period, the IC determines that the battery is not present and:

- 1. Enters Charge Configuration Mode;
- 2. Sets the FAULT bits to 111 (no battery) and resets the SAFETY registers; and
- 3. Disables auto-charging until the next PWRIN POR.

Battery Short-Circuit Protection

If the battery voltage is below the short-circuit threshold (V_{SHORT}); a linear current source, I_{SHORT}, supplies VBAT until V_{BAT} > V_{SHORT}.

Charger Status / Fault Status

The STAT pin indicates the operating condition of the IC and provides a fault indicator for interrupt-driven systems. When a fault condition occurs, the STAT pin pulses LOW for 125 μ s. If a new fault replaces the prior fault, STAT issues a new pulse.

The FAULT bits (R0[2:0]) indicate the type of fault in Charge Mode (see Table 14). FAULT bits return to 000 once R0 is read if the fault condition has cleared.

Charge Mode Control Bits

When set, the HZ_VBUS and HZ_VIN bits prevent charging from the VBUS or VIN input sources, respectively. The DIS pin prevents all charging when set, regardless of the state of the HZ bits.

Table 6. DIS Pin and HZ Bit Functionality

| Charging | DIS PIN | HZ |
|----------|---------|----|
| ENABLE | 0 | 0 |
| DISABLE | Х | 1 |
| DISABLE | 1 | Х |

Boost Mode

Boost Mode can be enabled when the IC is in 32-Second Mode (host sets TMR_RST before the t_{32SEC} expired) with the OTG pin and OPA_MODE bits as indicated in Table 7. The OTG ACTIVE state is 1 if OTG_PL =1, and 0 when OTG_PL =0.

If boost is active using the OTG pin, boost mode is initiated even if the HZ_VBUS = 1. The HZ_VBUS bit overrides the OPA_MODE bit.

Table 7. Enabling Boost

| OTG_E N | OTG PIN | HZ_VBU S | OPA_MOD E | BOOS T |
|------------|---------|-------------|--------------|-----------|
| 1 | ACTIVE | Х | Х | Enabled |
| 1 | Х | 0 | 1 | Enabled |
| 1 | ACTIVE | 0 | 0 | Disabled |
| 1 | ACTIVE | Х | 0 | Disabled |
| 0 | Х | 1 | Х | Disabled |

To remain in Boost Mode, the TMR_RST bit must be set by the host before the t_{32SEC} timer expires. If t_{32SEC} times out in Boost Mode; the IC reverts to High-Impedance Mode, pulses the STAT pin, sets the FAULT bits to 110, and resets the BOOST bit. POR or USB activity clears the fault condition.

The IC can operate its boost regulator while simultaneously charging from VIN. If the IC is charging from VIN when the boost regulator is enabled, charging pauses until the boost soft-start has completed.

Boost PWM Control

The IC uses a minimum on-time, and computed minimum offtime, to regulate V_{BUS} . The computed off-time is designed to keep the switching frequency constant near 3 MHz when the regulator's inductor current is continuous (CCM).

The regulator achieves excellent transient response by employing current-mode modulation. This technique causes the regulator to exhibit a load line. During CCM Mode, the output voltage drops slightly as the input current rises. With a constant V_{BAT} , this appears as a constant output resistance.

The "droop" caused by the output resistance when a load is applied allows the regulator to respond smoothly to load transients with no undershoot from the load line. This can be seen in Figure 34.

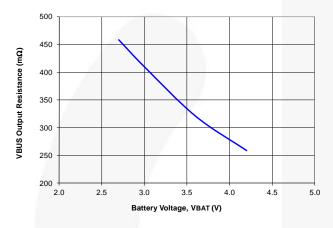


Figure 53. Output Resistance (ROUT)

 V_{BUS} as a function of I_{LOAD} can be computed when the regulator is in PWM Mode (continuous conduction) as:

$$V_{BUS} = 5.05 - R_{OUT} \bullet I_{LOAD}$$
 EQ. 1

At 3.6 V_{BAT} and I_{LOAD} = 300 mA, V_{BUS} would droop to about:

$$V_{BUS} = 5.05 - 0.32 \cdot 0.3 = 4.95V$$
 EQ. 2

At 2.7 V_{BAT} , with $I_{LOAD} = 200 \text{ mA}$, V_{BUS} would droop to about:

$$V_{BUS} = 5.05 - 0.45 \cdot 0.2 - 4.96V$$
 EQ. 3

Pulse Frequency Modulated (PFM) Mode

If V_{BUS} > VREF_{BOOST} (nominally 5.05 V) when the minimum off time has ended, the regulator enters PFM Mode. Boost pulses are inhibited until V_{BUS} < VREF_{BOOST}. The minimum on-time is increased to enable the output to pump up sufficiently with each PFM boost pulse. The regulator behaves like a constant on-time regulator, with the bottom of its output voltage ripple at 5.05 V in PFM Mode. Since PFM voltage ripple is typically 20 mV_{P-P}, VBUS_(PFM) is nominally 5.06 V.

| State | Description | Invoked When: | | | |
|-------|----------------------|--|--|--|--|
| SCHK | Short-Circuit Check | $V_{BAT} > V_{BUS}$ and $V_{BUS} < 1V$ | | | |
| LIN1 | Linear Startup | $V_{BAT} > 1V$ | | | |
| SS | Boost Soft-Start | $V_{BUS} < V_{BST}$ | | | |
| BST | Boost Operating Mode | $V_{BAT} > V_{UVLO}$ and SS completed | | | |

Shutdown State

When the boost regulator is shut down, Q3 is off, preventing current flow from VBAT to VBUS. Q1 is also off, which prevents current flow from VBUS to VBAT.

SCHK State

The SCHK state turns on a switch with an on-resistance of about 120 Ω from VBAT to VBUS and waits for V_{BUS} to rise to about 1 V before proceeding with boost soft-start. This prevents high current drain from the battery, which could occur if Q3 is turned on into a short circuit. If V_{BUS} fails to rise above 1 V within 8 ms, a boost overload fault is enunciated.

LIN1 State

A portion of Q3 is turned on (on-resistance = 1 Ω) to charge V_{BUS} from 1V to V_{PMID1}. V_{PMID1} is about 0.7 V below V_{BAT}. This state ends when V_{PMID1} - V_{BUS} < 0.4 V. If V_{BUS} fails to achieve V_{PMID1} - 0.4 V within 512 μ s, a boost overload fault is enunciated.

SS State

When $V_{\text{BUS}} > V_{\text{PMID1}} - 0.4 \text{ V}$, the boost regulator begins switching. The output slews up until V_{BUS} is within 10% of its setpoint; at which time, the regulation loop is closed and the boost reference is digitally stepped to 5.07 V.

If the output fails to achieve 90% of its setpoint (V_{BST}) within 512 μ s, a boost overload fault is enunciated.

BST State

This is the normal operating mode of the regulator.

Thermal

If the die temperature reaches 120°C while the boost and charger are both operating, charging stops for at least 10 ms, then resumes when the die temperature falls below 120°C.

Boost Fault States

A BOOST fault is enunciated by the STAT pin pulsing and FAULT status bits under any of the following conditions.

Table 9. Fault Status Bits during Boost Mode

| Fa | Fault Bit | | Fault Description | | | | | |
|----|-----------|-----------|--|--|--|--|--|--|
| B2 | B1 | B0 | Fault Description | | | | | |
| 0 | 0 | 0 | Normal (no fault) | | | | | |
| 0 | 0 | 1 | V _{BUS} > VBUS _{OVP} | | | | | |
| 0 | 1 | 0 | V_{BUS} fails to achieve the voltage required to advance to the next state during soft-start or sustained (>32 ms) current limit during the BST state. | | | | | |
| 0 | 1 | 1 | V _{BAT} < UVLO _{BST} | | | | | |
| 1 | 0 | 0 | N/A: This code will not appear | | | | | |
| 1 | 0 | 1 | Thermal shutdown | | | | | |
| 1 | 1 | 0 | Timer fault | | | | | |
| 1 | 1 | 1 | N/A: This code will not appear | | | | | |

Once a fault is triggered, the OPA_MODE bit is reset.

If the boost was started by setting the OTG pin and OTG_EN bits, the boost attempts to restart after a fault following a "cool-off" time of 128 ms.

VREF

The VREF pin provides bias current to the charging circuit while VIN is the power source. This pin follows PMID2, but its voltage is limited to 5.8 V. Up to 5 mA of current can be drawn from the VREF pin to power external devices.

LED Control

An LED driver provides a constant current to drive the anode of a charge indicator LED. The LED flashes during charging. The LED_CONTROL register provides control of the LED driver and can be programmed to flash the LED when charging is disabled.

LED_CONTROL is reset whenever the IC begins charging in 15-Minute Mode. This occurs after VBUS or VIN POR with a weak battery when t_{32SEC} is not running or when t_{32SEC} expires.

Recommended PCB Layout

To limit the high-voltage excursions and stresses on the chargers' internal switching MOSFETs, it is critical to limit the total loop length from PMID back to the GND return, including the length of the CMID bypass capacitors. The layout below achieves this goal.

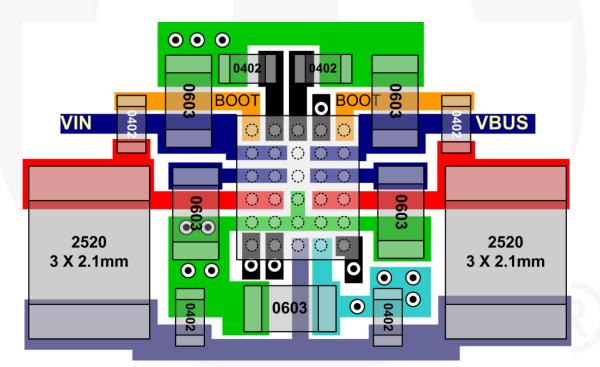


Figure 54. Recommended Layout for High-Current Charging, Using 2520 Inductors

I²C Interface

The serial interface is compatible with Standard, Fast, Fast Plus, and High-Speed Modes per the I²C-Bus® specifications. The SCL line is an input and its SDA line is a bi-directional open-drain output; it can only pull down the bus when active. The SDA line only pulls LOW during data reads and when signaling ACK. All data is shifted in MSB (bit 7) first.

Bus Timing

As shown in Figure 55, data is normally transferred when SCL is LOW. Data is clocked in on the rising edge of SCL. Typically, data transitions shortly at or after the falling edge of SCL to allow ample time for the data to set up before the next SCL rising edge.

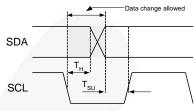
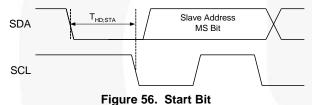
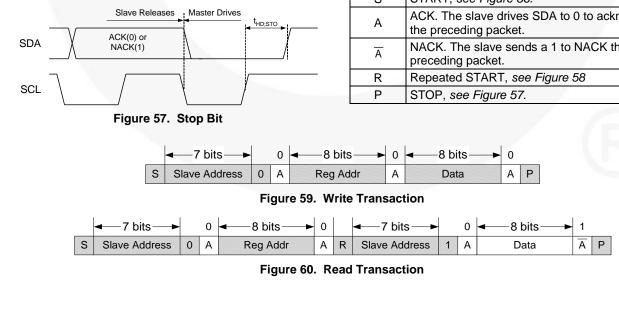


Figure 55. Data Transfer Timing

Each bus transaction begins and ends with SDA and SCL HIGH. A transaction begins with a START condition, which is defined as SDA transitioning from 1 to 0 with SCL HIGH, as shown in Figure 56.



A transaction ends with a STOP condition, which is defined as SDA transitioning from 0 to 1 with SCL HIGH, as shown in Figure 57.



During a read from the FAN54300 (see Figure 60), the master issues a "REPEATED START" after sending the register address and before resending the slave address. The REPEATED START is a 1-to-0 transition on SDA while SCL is HIGH, as shown in Figure 58.

High-Speed (HS) Mode

The protocols for High-Speed (HS), Low-Speed (LS), and Fast-Speed (FS) Modes are identical, except the bus speed for HS Mode is 3.4 MHz. HS Mode is entered when the bus master sends the HS master code 00001XXX after a START condition. The master code is sent in Fast or Fast-Plus Mode (less than 1 MHz clock). Slaves do not ACK this transmission.

The master then generates a REPEATED START condition (see Figure 58) that causes all slaves on the bus to switch to HS Mode. The master then sends I²C packets, as described above, using the HS Mode clock rate and timing.

The bus remains in HS Mode until a stop bit (Figure 57) is sent by the master. While in HS Mode, packets are separated by REPEATED START conditions (Figure 58).

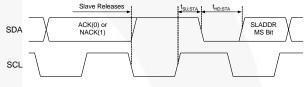


Figure 58. Repeated Start Timing

Read and Write Transactions

The following figures outline the sequences for data read and write. Bus control is signified by the shading of the packet,

Slave Drives Bus Master Drives Bus and defined as

All addresses and data are MSB first.

Table 10. Bit Definitions for Figure 59 and Figure 60

| Symbol | Definition |
|--------|---|
| S | START, see Figure 56. |
| А | ACK. The slave drives SDA to 0 to acknowledge the preceding packet. |
| Ā | NACK. The slave sends a 1 to NACK the preceding packet. |
| R | Repeated START, see Figure 58 |
| Р | STOP, see Figure 57. |

Register Descriptions

Table 11. I²C Slave Address

| Hex | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | |
|-----|---|---|---|---|---|---|---|------------------|-------------|
| D4 | 1 | 1 | 0 | 1 | 0 | 1 | 0 | R/W | VIN Charger |
| D6 | 1 | 1 | 0 | 1 | 0 | 1 | 1 | R/\overline{W} | USB Charger |

Table 12. I²C Register Address

| Table 121 To Registo | | | | | | | | | | | |
|----------------------|------------------|---------------|---------|---|---|---|---|---|---|---|---|
| Name | Register Address | Slave Address | Affects | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| CONTROL0_U | 0 | D6 | USB | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |
| CONTROL1_U | 1 | D6 | USB | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 |
| OREG_U | 2 | D6 | USB | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 0 |
| IC_INFO_U | 3 | D6 | Both | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 1 |
| IBAT_U | 4 | D6 | USB | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 0 |
| SP_CHARGER_U | 5 | D6 | USB | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 1 |
| SAFE_U | 6 | D6 | USB | 0 | 0 | 0 | 0 | 0 | 1 | 1 | 0 |
| CONTROL0_V | 0 | D4 | VIN | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |
| CONTROL1_V | 1 | D4 | VIN | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 |
| OREG_V | 2 | D4 | VIN | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 0 |
| IC_INFO_V | 3 | D4 | Both | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 1 |
| IBAT_V | 4 | D4 | VIN | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 0 |
| SP_CHARGER_V | 5 | D4 | VIN | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 1 |
| SAFE_V | 6 | D4 | VIN | 0 | 0 | 0 | 0 | 0 | 1 | 1 | 0 |
| LED_CONTROL | 7 | D4/D6 | Both | 0 | 0 | 0 | 0 | 0 | 1 | 1 | 1 |
| CHARGE_STATUS | 8 | D4/D6 | Both | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 0 |
| INPUT_STATUS | 9 | D4/D6 | Both | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 1 |
| DIE_REV | 14 | D4/D6 | Both | 0 | 0 | 0 | 1 | 0 | 1 | 0 | 0 |

| Bit | Name | Туре | | | | | D | escription | | | |
|-----|----------|------|---|---|------------------------------------|---|--|--|--|--|--|
| CO | NTROL0_U | | | Reg Addr: 0 Slave Addr: D6 Default = x1 | | | | | | | |
| 7 | TMR_RST | W | Writi | ing a | a 1 i | esets the t _{32SEC} timer. Writi | ng a 0 ł | nas no effect. | | | |
| 1 | OTG | R | Retu | ırns | the | OTG pin level (1 = OTG pin | HIGH) | | | | |
| 6 | EN_STU | R/W | 0: 1: | | | | | | | | |
| | | | | | • | r status JSB Charger Status Bits | | | | | |
| 5:4 | STAT II | R | | 00 Normal (no fault) / Ready | | | | | | | |
| 5.4 | STAT_U | ĸ | | 01 | | Charge in progress from L | ISB sou | irce | | | |
| | | | _ | 10 | | Charge done | | | | | |
| | | | | 11 | | USB charger fault | | | | | |
| 3 | BOOST | R | 0: 1: | | | oost is not active. oost is active. | | | | | |
| | | | | | | | | | | | |
| | | | | | | JSB Charger and OTG Boo JSB Fault Bits | st Fault | S | | | |
| | | | Tab | | 4. L | JSB Fault Bits | st Fault | | | | |
| | | | Tab | le 1 | 4. L | - | st Fault | s Boost Mode | | | |
| | | | Tab | le 14 Bits | 4. L | JSB Fault Bits | | | | | |
| 0.0 | | D | Tab I 2 | le 14 Bits 1 | 4. L 0 | JSB Fault Bits Charger Mode | Norma | Boost Mode | | | |
| 2:0 | FAULT_U | R | Tab 2 0 | le 14 Bits 1 0 | 4. L 0 | JSB Fault Bits Charger Mode Normal (no fault) | Norma V _{BUS} > | Boost Mode | | | |
| 2:0 | FAULT_U | R | Tab 2 0 0 | le 14 Bits 1 0 | 4. l 0 1 | USB Fault Bits Charger Mode Normal (no fault) V _{BUS} > VBUS _{OVP} | Norma V _{BUS} > Boost | Boost Mode al (no fault) > VBUS _{OVP} | | | |
| 2:0 | FAULT_U | R | Tab 2 0 0 0 0 | le 14 Bits 1 0 1 | 4 . 1 0 | USB Fault Bits Charger Mode Normal (no fault) V _{BUS} > VBUS _{OVP} Sleep Mode: V _{BUS} < V _{BAT} | Norma V _{BUS} > Boost V _{BAT} < | Boost Mode al (no fault) > VBUS _{OVP} overload | | | |
| 2:0 | FAULT_U | R | Table 2 0 0 0 0 0 | le 14 Bits 1 0 0 1 1 | 4 . 1 0 1 0 | JSB Fault Bits Charger Mode Normal (no fault) V _{BUS} > VBUS _{OVP} Sleep Mode: V _{BUS} < V _{BAT} Poor USB input source | Norma V _{BUS} > Boost V _{BAT} < N/A: 1 | Boost Mode al (no fault) > VBUS _{OVP} overload < UVLO _{BST} | | | |
| 2:0 | FAULT_U | R | Tab 2 0 0 0 0 1 | le 14 Bits 1 0 0 1 1 0 | 4. L 0 1 0 1 0 | USB Fault Bits Charger Mode Normal (no fault) VBUS > VBUSOVP Sleep Mode: VBUS < VBAT Poor USB input source Battery OVP | Norma V _{BUS} > Boost V _{BAT} < N/A: 1 | Boost Mode al (no fault) > VBUS _{OVP} overload < UVLO _{BST} This code will not appear nal shutdown | | | |

Note:

7. Default values are in **bold** text.

| Bit | Name | Туре | Description |
|--|---|--|---|
| CO | NTROL1_U | | Reg Addr: 1 Slave Addr: D6 Default = 0011 0000 |
| | | | USB bus current limit |
| | | | Table 15. IBUSLIM: USB bus current limit |
| | | | [7:6] IBUS Current Limit |
| 7:6 | IBUSLIM | R/W | 00 100 mA |
| | | | 01 500 mA |
| | | | 10 800 mA |
| | | | 11 No limit |
| | | | Weak Battery Threshold. This register determines V _{LOWV} threshold when V _{BUS} is charging. |
| | | | Table 16. V _{Lowv} : Weak Battery Threshold |
| | | | [5:4] IBUS Current Limit |
| 5:4 | VLOWV_U | R/W | 00 3.4 V |
| | | | 01 3.5 V |
| | | | 10 3.6 V |
| | | | 11 3.7 V |
| 3 | TE_U | R/W | 0: Charge termination is disabled when charging from USB. |
| 5 | 12_0 | 1 1/ 1 1 | 1: Charge termination is enabled for USB charging. |
| | | | |
| S | CE# 11 | | 0: USB charger is enabled. |
| 2 | CE#_U | R/W | 1: USB charger is disabled. This bit is set when t _{15MIN} expires, regardless of which input source is |
| | | | |
| 2 | CE#_U HZ_U | R/W R/W | 1: USB charger is disabled. This bit is set when t_{15MIN} expires, regardless of which input source is charging. |
| | HZ_U OPA_ | R/W | USB charger is disabled. This bit is set when t_{15MIN} expires, regardless of which input source is charging. USB charger is not in High-Impedance Mode. USB charger is in High-Impedance Mode. Boost Mode disabled unless enabled with the OTG pin and OTG_EN HIGH. |
| 1 | HZ_U OPA_ MODE | | USB charger is disabled. This bit is set when t_{15MIN} expires, regardless of which input source is charging. USB charger is not in High-Impedance Mode. USB charger is in High-Impedance Mode. Boost Mode disabled unless enabled with the OTG pin and OTG_EN HIGH. Boost Mode enabled unless HZ_U is set. |
| 1 | HZ_U OPA_ | R/W | 1: USB charger is disabled. This bit is set when t _{15MIN} expires, regardless of which input source is charging. 0: USB charger is not in High-Impedance Mode. 1: USB charger is in High-Impedance Mode. 0: Boost Mode disabled unless enabled with the OTG pin and OTG_EN HIGH. 1: Boost Mode enabled unless HZ_U is set. Reg Addr: 2 |
| 1 0 ORE | HZ_U OPA_ MODE | R/W | 1: USB charger is disabled. This bit is set when t _{15MIN} expires, regardless of which input source is charging. 0: USB charger is not in High-Impedance Mode. 1: USB charger is in High-Impedance Mode. 0: Boost Mode disabled unless enabled with the OTG pin and OTG_EN HIGH. 1: Boost Mode enabled unless HZ_U is set. Reg Addr: 2 Slave Addr: D6 Default = 0000 1010 Charger output "float" voltage when charging from USB source. |
| 1 0 0RE 7:2 | HZ_U OPA_ MODE EG_U OREGU | R/W R/W R/W | 1: USB charger is disabled. This bit is set when t _{15MIN} expires, regardless of which input source is charging. 0: USB charger is not in High-Impedance Mode. 1: USB charger is in High-Impedance Mode. 0: Boost Mode disabled unless enabled with the OTG pin and OTG_EN HIGH. 1: Boost Mode enabled unless HZ_U is set. Reg Addr: 2 Slave Addr: D6 Default = 0000 1010 Charger output "float" voltage when charging from USB source. Programmable from 3.5 to 4.44 V in 20 mV increments. Defaults to 000010 (3.54 V) (see Table 5). |
| 1 0 ORE | HZ_U OPA_ MODE EG_U | R/W R/W | 1: USB charger is disabled. This bit is set when t _{15MIN} expires, regardless of which input source is charging. 0: USB charger is not in High-Impedance Mode. 1: USB charger is in High-Impedance Mode. 0: Boost Mode disabled unless enabled with the OTG pin and OTG_EN HIGH. 1: Boost Mode enabled unless HZ_U is set. Reg Addr: 2 Slave Addr: D6 Default = 0000 1010 Charger output "float" voltage when charging from USB source. Programmable from 3.5 to 4.44 V in 20 mV increments. Defaults to 000010 (3.54 V) (see Table 5). |
| 1 0 0RE 7:2 1 | HZ_U OPA_ MODE EG_U OREGU OTG_PL | R/W R/W R/W | USB charger is disabled. This bit is set when t_{15MIN} expires, regardless of which input source is charging. USB charger is not in High-Impedance Mode. USB charger is in High-Impedance Mode. Boost Mode disabled unless enabled with the OTG pin and OTG_EN HIGH. Boost Mode enabled unless HZ_U is set. Reg Addr: 2 Slave Addr: D6 Default = 0000 1010 Charger output "float" voltage when charging from USB source. Programmable from 3.5 to 4.44 V in 20 mV increments. Defaults to 000010 (3.54 V) (see Table 5). OTG pin is active LOW. OTG pin does not enable boost when HIGH. |
| 1 0 0RE 7:2 1 0 | HZ_U OPA_ MODE EG_U OREGU OTG_PL OTG_EN | R/W R/W R/W | 1: USB charger is disabled. This bit is set when t _{15MIN} expires, regardless of which input source is charging. 0: USB charger is not in High-Impedance Mode. 1: USB charger is in High-Impedance Mode. 0: Boost Mode disabled unless enabled with the OTG pin and OTG_EN HIGH. 1: Boost Mode enabled unless HZ_U is set. Reg Addr: 2 Slave Addr: D6 Default = 0000 1010 Charger output "float" voltage when charging from USB source. Programmable from 3.5 to 4.44 V in 20 mV increments. Defaults to 000010 (3.54 V) (see Table 5). 0: OTG pin is active LOW. 1: OTG pin does not enable boost when HIGH. 1: OTG pin enables boost when HIGH. |
| 1 0 0RE 7:2 1 0 IC_I | HZ_U OPA_ MODE EG_U OREGU OTG_PL OTG_EN NFO_U | R/W R/W R/W | 1: USB charger is disabled. This bit is set when t _{15MIN} expires, regardless of which input source is charging. 0: USB charger is not in High-Impedance Mode. 1: USB charger is in High-Impedance Mode. 0: Boost Mode disabled unless enabled with the OTG pin and OTG_EN HIGH. 1: Boost Mode enabled unless HZ_U is set. Reg Addr: 2 Slave Addr: D6 Default = 0000 1010 Charger output "float" voltage when charging from USB source. Programmable from 3.5 to 4.44 V in 20 mV increments. Defaults to 000010 (3.54 V) (see Table 5). 0: OTG pin is active LOW. 1: OTG pin is active HIGH. 0: OTG pin does not enable boost when HIGH. 1: OTG pin enables boost when HIGH. 1: OTG pin enables boost when HIGH. |
| 1 0 0 7:2 1 0 IC_I 7:5 | HZ_U OPA_ MODE EG_U OREGU OTG_PL OTG_EN NFO_U VENDOR | R/W R/W R/W R/W R/W | 1: USB charger is disabled. This bit is set when t _{15MIN} expires, regardless of which input source is charging. 0: USB charger is not in High-Impedance Mode. 1: USB charger is in High-Impedance Mode. 0: Boost Mode disabled unless enabled with the OTG pin and OTG_EN HIGH. 1: Boost Mode enabled unless HZ_U is set. Reg Addr: 2 Slave Addr: D6 Default = 0000 1010 Charger output "float" voltage when charging from USB source. Programmable from 3.5 to 4.44 V in 20 mV increments. Defaults to 000010 (3.54 V) (see Table 5). 0: OTG pin is active LOW. 1: OTG pin does not enable boost when HIGH. 1: OTG pin enables boost when HIGH. Reg Addr: 3 Slave Addr: D4 or D6 Default = 100x x000 |
| 1 0 0RE 7:2 1 0 IC_I 7:5 4:3 | HZ_U OPA_ MODE EG_U OREGU OTG_PL OTG_EN NFO_U VENDOR PN_U | R/W R/W R/W R/W R/W R/W | 1: USB charger is disabled. This bit is set when t _{15MIN} expires, regardless of which input source is charging. 0: USB charger is not in High-Impedance Mode. 1: USB charger is in High-Impedance Mode. 0: Boost Mode disabled unless enabled with the OTG pin and OTG_EN HIGH. 1: Boost Mode enabled unless enabled with the OTG pin and OTG_EN HIGH. 1: Boost Mode enabled unless HZ_U is set. Reg Addr: 2 Slave Addr: D6 Default = 0000 1010 Charger output "float" voltage when charging from USB source. Programmable from 3.5 to 4.44 V in 20 mV increments. Defaults to 000010 (3.54 V) (see Table 5). 0: OTG pin is active LOW. 1: OTG pin does not enable boost when HIGH. 1: OTG pin does not enable boost when HIGH. 1: OTG pin enables boost when HIGH. Reg Addr: 3 Slave Addr: D4 or D6 Default = 100x x000 100: Identifies Fairchild as the supplier. Part number bits. FAN54300 = 10 |
| 1 0 0 7:2 1 0 IC_I 7:5 4:3 2:0 | HZ_U OPA_ MODE EG_U OREGU OTG_PL OTG_EN NFO_U VENDOR PN_U REV | R/W R/W R/W R/W R/W | 1: USB charger is disabled. This bit is set when t _{15MIN} expires, regardless of which input source is charging. 0: USB charger is not in High-Impedance Mode. 1: USB charger is in High-Impedance Mode. 0: Boost Mode disabled unless enabled with the OTG pin and OTG_EN HIGH. 1: Boost Mode enabled unless HZ_U is set. Reg Addr: 2 Slave Addr: D6 Default = 0000 1010 Charger output "float" voltage when charging from USB source. Programmable from 3.5 to 4.44 V in 20 mV increments. Defaults to 000010 (3.54 V) (see Table 5). 0: OTG pin is active LOW. 1: OTG pin is active HIGH. 0: OTG pin enables boost when HIGH. 1: OTG pin sactive LOW. 1: Part number bits. FAN54300 = 10 IC Rey Addr: 3 Slave Addr: D4 or D6 Default = 100x x000 100: Identifies Fairchild as the supplier. Part number bits. FAN54300 = 10 IC |
| 1 0 7:2 1 0 IC_I 7:5 4:3 2:0 DIE | HZ_U OPA_ MODE CG_U OREGU OTG_PL OTG_EN OTG_EN VENDOR PN_U REV REV | R/W R/W R/W R/W R/W R/W | 1: USB charger is disabled. This bit is set when t _{15MIN} expires, regardless of which input source is charging. 0: USB charger is not in High-Impedance Mode. 1: USB charger is in High-Impedance Mode. 0: Boost Mode disabled unless enabled with the OTG pin and OTG_EN HIGH. 1: Boost Mode enabled unless enabled with the OTG pin and OTG_EN HIGH. 1: Boost Mode enabled unless HZ_U is set. Reg Addr: 2 Slave Addr: D6 Default = 0000 1010 Charger output "float" voltage when charging from USB source. Programmable from 3.5 to 4.44 V in 20 mV increments. Defaults to 000010 (3.54 V) (see Table 5). 0: OTG pin is active LOW. 1: OTG pin is active HIGH. 0: OTG pin enables boost when HIGH. 1: OTG pin stactive LOW. 1: OTG pin enables boost when HIGH. 1: OTG pin enables boost when HIGH. 1: OTG pin stactive HIGH. 1: OTG pin stactive LOW. 1: OTG pin stactive HIGH. <td< td=""></td<> |
| 1 0 0 7:2 1 0 IC_I 7:5 4:3 2:0 | HZ_U OPA_ MODE EG_U OREGU OTG_PL OTG_EN NFO_U VENDOR PN_U REV | R/W R/W R/W R/W R/W R/W | 1: USB charger is disabled. This bit is set when t _{15MIN} expires, regardless of which input source is charging. 0: USB charger is not in High-Impedance Mode. 1: USB charger is in High-Impedance Mode. 0: Boost Mode disabled unless enabled with the OTG pin and OTG_EN HIGH. 1: Boost Mode enabled unless HZ_U is set. Reg Addr: 2 Slave Addr: D6 Default = 0000 1010 Charger output "float" voltage when charging from USB source. Programmable from 3.5 to 4.44 V in 20 mV increments. Defaults to 000010 (3.54 V) (see Table 5). 0: OTG pin is active LOW. 1: OTG pin is active HIGH. 0: OTG pin enables boost when HIGH. 1: OTG pin sactive LOW. 1: Part number bits. FAN54300 = 10 IC Rey Addr: 3 Slave Addr: D4 or D6 Default = 100x x000 100: Identifies Fairchild as the supplier. Part number bits. FAN54300 = 10 IC |

| Bit | Name | Туре | | | | | | | Descr | iption | | | | | | |
|------|----------|----------------|-------------------|--------------------|--------------------------|--------------------|----------------------|-----------------------|---------------------|---|-----|--|--|-------|--|--|
| IBAT | _U | | | Re | g Addr: | 4 | | | Slav | ve Addr: D6 Default = 0000 1001 | | | | | | |
| 7 | RESETU | W | Writing (Reg6) | a 1 re , to the | sets all r eir defaul | egister ts. Wri | rs progi ting a C | rammed) has no | with sla effect. | ave address D4, except the Safety register Read returns 0. | | | | | | |
| | | | Sets th | e max | imum ch | arge c | urrent (| I _{CHARGE}) | when c | charging from VBUS when IO_LEVELU = 0. | | | | | | |
| | | | Table | 17. Ia | CHARGE A | s a Fi | unctio | n of th | e ICHG | BU Bits and R _{SENSE} Resistor Value | | | | | | |
| | | | BIN | HE | | | OCHARGE | | | | | | | | | |
| | | | | | | | | | | _ | (m) | | | 100mΩ | | |
| 6:4 | ICHGU | | 000 | 0 | | | 550 | 374 | 704 | | | | | | | |
| | | R/W | 001 | 0 | | | 650 750 | 442 510 | 832 960 | | | | | | | |
| | | | 010 | 0 | - | | 850 | 578 | 1088 | | | | | | | |
| | | | 100 | 0 | | | 950 | 646 | 1216 | | | | | | | |
| | | | 100 | 0 | | | ,050 | 714 | 1344 | | | | | | | |
| | | | 110 | 0 | - | | ,150 | 782 | 1472 | | | | | | | |
| | | | 111 | 0 | | | ,250 | 850 | 1600 | | | | | | | |
| | | | - | at whe | | | | | | ger current is limited to 1250 mA (R _{SENSE} = 68m | | | | | | |
| 3 | Reserved | R | This bit | t returr | าร 1. | | | | | | | | | | | |
| | | | Sets th | e curre | ent at wh | ich cha | arging t | erminat | es wher | n charging from VBUS if the TE bit is set. | | | | | | |
| | | | Table Resis | | | ermir | nation | Currei | nt as a | Function of ITERM bits and R _{SENSE} | | | | | | |
| | | | BIN | HEX | V _{RSENSE} | ITER | տ (mA) | 7 | | | | | | | | |
| | | | DIN | | (mV) | | 100m | 2 | | | | | | | | |
| | ITERNAL | - • • • | 000 | 00 | 3.3 | 49 | 33 | | | | | | | | | |
| 2:0 | ITERMU | R/W | 001 | 01 | 6.6 | 97 | 66 | | | | | | | | | |
| 2:0 | | | 010 | 02 | 9.9 | 146 | 99 | | | | | | | | | |
| 2:0 | | | 011 | 03 | 13.2 | 194 | 132 | | | | | | | | | |
| 2:0 | | | | 0.4 | 16.5 | 243 | 165 | | | | | | | | | |
| 2:0 | | | 100 | 04 | | | | | | | | | | | | |
| 2:0 | | | 100 101 | 04 | 19.8 | 291 | 198 | | | | | | | | | |
| 2:0 | | | | - | | 291 340 | 198 231 | | | | | | | | | |

| Bit | Name | Туре | | Description | | | | |
|-----|-----------|------|---|---|--|--|--|--|
| SP_ | CHARGER_U | I | Reg Addr: 5 | Slave Addr: D6 Default = 0x1x x100 | | | | |
| 7 | Reserved | R | This bit returns 0. | | | | | |
| 6 | VBUS_CON | R | Iirror of INPUT_STATUS[5] (see INPUT_STATUS register description) | | | | | |
| 5 | IO_LEVEL | R/W | | PIOCHARGE bits for charging from VBUS. Poltage across R_{SENSE} for output current control is set to nΩ, 221 mA for 100 mΩ). | | | | |
| 4 | SPU | R | VBUS is not PWM charging. | nput power source is able to stay above V_{SP} . SPU = 0 when and controlling the charging current. | | | | |
| 3 | VIN_CON | R | Mirror of INPUT_STATUS[7] (see I | NPUT_STATUS register description) | | | | |

| Bit | Name | Туре | | | | | Description |
|-----|----------|-------|---|---|--|--|---|
| | | | Sets the below the | special is voltag | charger cor je, battery c | ntrol loop refe arrent is redu | rence voltage when charging from V_{BUS} . If V_{BUS} faced until the input voltage is at or above V_{SP} . |
| | | | Table 1 | 9. Ven | Special Cl | harger Refe | rence Voltage |
| | | | DEC | BIN | V _{SP} | | |
| | | | 0 | 000 | 4.21 | | |
| 2:0 | VSPU | R/W | 1 | 001 | 4.29 | | |
| 2.0 | | 10/00 | 2 | 010 | 4.37 | | |
| | | | 3 | 011 | 4.45 | | |
| | | | 4 | 100 | 4.53 | | |
| | | | 5 | 101 | 4.61 | | |
| | | | 6 | 110 | 4.69 | | |
| | | | 7 | 111 | 4.77 | | |
| SAF | E_U | | 1 | eg Add | | | Slave Addr: D6 Default = 0100 0000 |
| 7 | Reserved | R | This bit r | eturns (|). | | |
| | | | Any atter ISAFEU. | | rite a value | to ICHGU hi | gher than the contents of ISAFEU sets ICHGU = |
| | | | Table 2 | 0. USE | Charging | I I _{CHARGE} Lin | nit as a Function of the ISAFEU Bits |
| | | | BIN | HEX | V _{RSENSE} | I _{SAFE} (mA) | |
| | | | BIN | HEX | | 68mΩ 100mΩ | 2 |
| 6:4 | ISAFEU | R/W | 000 | 00 | | 550 374 | |
| | | | 001 | 01 02 | | 650 442 750 510 | - |
| | | | 010 | 02 | | 850 578 | - |
| | | | 100 | 00 | | 950 646 | - |
| | | | 101 | 05 | | ,050 714 | |
| | | | <u>110</u> 111 | 06 07 | | ,150 782 ,250 850 | _ |
| | | | Anv atter | mpt to v | | | at is higher than the value in the Max. OREG col |
| | | | | | | Max OREG. | |
| | | | | | | | |
| | | | | 1. V _{ore} | _G Limit as | a Function | of the VSAFEU Bits when Charging from |
| | | | VBUS | | Max ORE | G VOREG | _ |
| | | | VBUS DEC | BIN | Max ORE (REG2[7: | G VOREG 2]) MAX | _ |
| | | | VBUS DEC 0 | BIN 0000 | Max ORE (REG2[7: 100011 | G VOREG 2]) MAX 4.20 | _ |
| | | | VBUS DEC 0 1 | BIN 0000 0001 | Max ORE (REG2[7: 100011 100100 | EG VOREG 2]) MAX 4.20 4.22 | _ |
| | | | VBUS DEC 0 | BIN 0000 | Max ORE (REG2[7: 100011 | G VOREG MAX 4.20 4.22 4.24 | _ |
| 3:0 | VSAFEU | R/W | VBUS DEC 0 1 2 | BIN 0000 0001 0010 | Max ORE (REG2[7: 100011 100100 100101 | G VOREG 2]) MAX 4.20 4.22 4.24 4.26 | _ |
| 3:0 | VSAFEU | R/W | VBUS DEC 0 1 2 3 4 5 | BIN 0000 0001 0010 0011 0100 0101 | Max ORE (REG2[7: 100011 100100 100101 100110 100111 101000 | G VOREG 2]) MAX 4.20 4.22 4.24 4.26 4.28 4.30 | _ |
| 3:0 | VSAFEU | R/W | VBUS DEC 0 1 2 3 4 5 6 | BIN 0000 0001 0010 0011 0100 0101 0110 | Max ORE (REG2[7:: 100011 100100 100101 100110 100111 101000 101001 | EG VOREG 2]) MAX 4.20 4.22 4.24 4.24 4.26 4.28 4.30 4.30 | _ |
| 3:0 | VSAFEU | R/W | VBUS DEC 0 1 2 3 4 5 6 7 | BIN 0000 0001 0010 0011 0100 0101 0110 0111 | Max ORE (REG2[7:: 1000101 100100 100110 100110 100111 101000 101001 101010 | EG VOREG 2]) MAX 4.20 4.22 4.24 4.24 4.26 4.28 4.30 4.32 4.32 4.32 4.32 4.32 | _ |
| 3:0 | VSAFEU | R/W | VBUS DEC 0 1 2 3 4 5 6 7 8 | BIN 0000 0001 0010 0011 0100 0101 0110 0111 1000 | Max ORE (REG2[7:: 1000101 100100 100110 100110 100111 101000 101001 101010 | EG VOREG 2]) MAX 4.20 4.22 4.24 4.26 4.28 4.30 4.32 4.32 4.32 4.34 4.34 4.36 | _ |
| 3:0 | VSAFEU | R/W | VBUS DEC 0 1 2 3 4 5 6 7 8 9 | BIN 0000 0001 0010 0011 0100 0101 0110 0111 1000 1001 | Max ORE (REG2[7:: 1000100 100100 100110 100110 101000 101001 101010 101010 101011 | EG VOREG 2]) MAX 4.20 4.22 4.24 4.26 4.28 4.30 4.32 4.34 4.34 4.36 4.38 4.38 | _ |
| 3:0 | VSAFEU | R/W | VBUS DEC 0 1 2 3 4 5 6 7 8 9 10 | BIN 0000 0001 0010 0100 0101 0100 0111 1000 1001 1001 | Max ORE (REG2[7:: 100011 100100 100101 100110 101010 101001 101010 101011 101000 101011 | EG VOREG 2]) MAX 4.20 4.22 4.24 4.26 4.28 4.30 4.32 4.34 4.34 4.36 4.38 4.38 4.38 4.40 | _ |
| 3:0 | VSAFEU | R/W | VBUS DEC 0 1 2 3 4 5 6 7 8 9 | BIN 0000 0001 0010 0011 0100 0101 0110 0111 1000 1001 | Max ORE (REG2[7:: 1000100 100100 100110 100110 101000 101001 101010 101010 101011 | EG VOREG 2]) MAX 4.20 4.22 4.24 4.26 4.26 4.30 4.32 4.32 4.34 4.36 4.34 4.36 4.38 4.38 4.40 4.42 | _ |
| 3:0 | VSAFEU | R/W | VBUS DEC 0 1 2 3 4 5 6 7 8 9 10 11 | BIN 0000 0001 0010 0011 0100 0101 0111 1000 1001 1010 1011 | Max ORE (REG2[7:: 100011 100100 100100 100111 101000 101001 101010 101011 101100 101101 | EG VOREG 2]) MAX 4.20 4.22 4.24 4.26 4.28 4.30 4.30 4.32 4.30 4.34 4.34 4.36 4.38 4.38 4.40 4.42 | _ |
| 3:0 | VSAFEU | R/W | VBUS DEC 0 1 2 3 4 5 6 7 8 9 10 11 12 | BIN 0000 0001 0010 0010 0101 0100 0111 1000 1001 1011 1000 | Max ORE (REG2[7:: 100011 100100 100100 100111 101000 101001 101010 101011 101100 101101 | EG VOREG 2]) MAX 4.20 4.22 4.24 4.26 4.26 4.30 4.32 4.34 4.34 4.36 4.34 4.36 4.38 4.36 4.40 4.44 4.44 4.44 | _ |

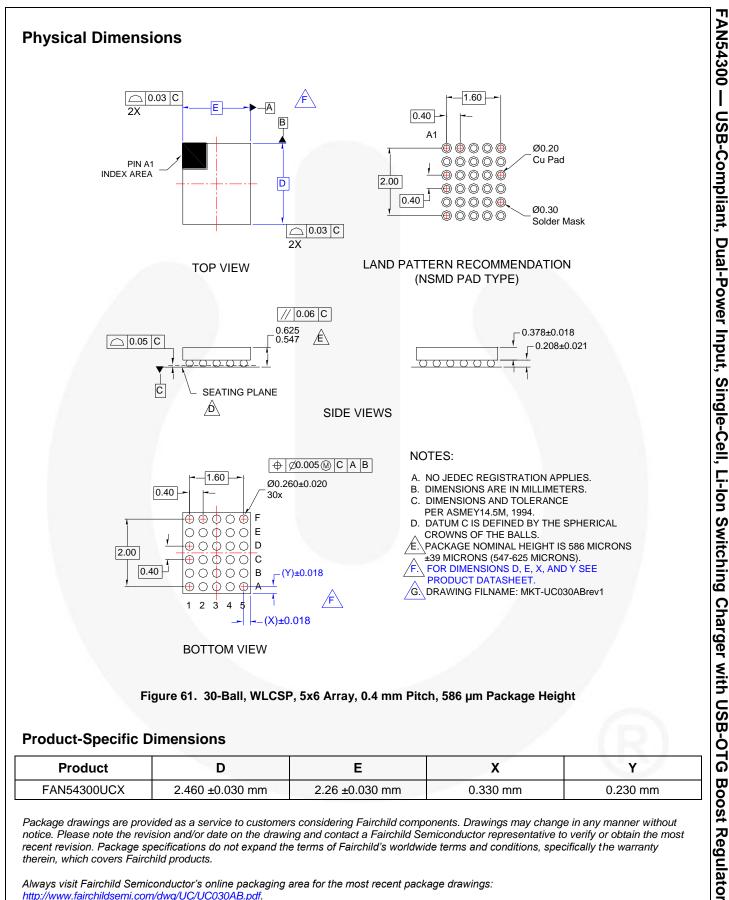
| Bit | Name | Туре | | Description |
|-----|----------|------|--|---|
| CON | NTROL0_V | | Reg Addr: 0 | Slave Addr: D4 Default = x1xx 0xxx |
| | TMR_RST | W | Writing a 1 resets the t _{32SEC} timer. Writing a | 0 has no effect. |
| | SRST | R | Returns the SRST pin level (1 = SRST pin | HIGH). |
| 6 | EN_STV | R/W | 0: STAT pin does not go LOW when cha 1: STAT pin function is enabled for V₁ | |
| 5:4 | STAT_V | R | Table 22. VIN Charger Status Bits00Normal (no fault)01Charge in progress from VIN source10Charge Done11VIN charger fault | |
| 3 | Reserved | R | This bit returns 0. | |
| 5 | Reserved | K | This bit returns 0. Delineates VIN Charger Faults Table 23. VIN Charger Fault Bits | |
| | | | Bits Charger Mode 2 1 0 | |
| | FAULT_V | | 0 0 0 Normal (no fault) | |
| 2:0 | | R | 0 0 1 V _{IN} > VIN _{OVP} | |
| | | | 0 1 0 Sleep Mode: V _{IN} < V _{BAT} | |
| | | | 0 1 1 Poor VIN input source | |
| | | | 1 0 0 Battery OVP | |
| | | | 1 0 1 Thermal shutdown | |
| | | | 1 1 0 Timer fault | |
| | | | 1 1 1 No battery | |
| COI | NTROL1_V | | Reg Addr: 1 | Slave Addr: D4 Default = 0111 0000 |
| 7:6 | Reserved | R/W | These bits have no effect on IC operation. VIN. | Input current is not limited by the IC when charging from |
| 5:4 | VLOWV_V | R/W | See Table 16. VLOWV: Weak Battery Thresho | ld |
| 3 | TE_V | R/W | 0: Charge termination is disabled when1: Charge termination is enabled for VIN | |
| 2 | CE#_V | R/W | 0: VIN charger is enabled.1: VIN charger is disabled. This bit is set charging. | when t_{15MIN} expires, regardless of which input source is |
| 1 | HZ_V | R/W | 0: VIN charger is not in High-Impedan1: VIN charger is in High-Impedance Model | |
| 0 | Reserved | R | This bit returns 0. | |
| ORE | EG_V | | Reg Addr: 2 | Slave Addr: D4 Default = 0000 1010 |
| 7:2 | OREGV | R/W | Charger output "float" voltage when chargin Programmable from 3.5 to 4.44 V in 20 mV | ng from VIN source. increments. Defaults to 000010 (3.54 V) <i>(see Table 5)</i> . |
| 1:0 | Reserved | R | These bits return 10. | |
| | NFO_V | | Reg Addr: 3 | Slave Addr: D4 Default = 100x x000 |
| 7:5 | VENDOR | R | 100: Identifies Fairchild as the supplier. | |
| 4:3 | PN_V | R | Part number bits: FAN54300 = 00 | |
| 2:0 | REV | R | IC Revision: Revision is 1.X, where X is the | decimal of these 3 hits |

| Description | |
|---|---|
| Slave Addr: D4 Default = 000 | 0 0001 |
| d with slave address D4, except the Sa Read returns 0. | fety register (Reg6 |
|) when charging from VIN when IO_LE | VELV = 0. |
| of the ICHGV Bits and $R_{\mbox{\scriptsize SENSE}}$ Resist | or Value |
| | |
| 2 | |
| | |
| | |
| | |
| | |
| | |
| - | |
| - | |
| - | |
| _ | |
| _ | |
| | |
| 10 results in ICHGV = 1010. | |
| tes if the TE bit is set: | |
| nt as a Function of the ITERM bit | s and Results |
| | S and RSENSE |
| | |
| | |
| | |
| | |
| | |
| | |
| | |
| | |
| | |
| | |
| 011 03 13.2 194 132 100 04 16.5 243 165 101 05 19.8 291 198 110 06 23.1 340 231 111 07 26.4 388 264 | 100 04 16.5 243 165 101 05 19.8 291 198 110 06 23.1 340 231 |
| | |

| Bit | Name | Туре | | Description | | | | | |
|-----|-----------|------|---|--|--|--|--|--|--|
| SP_ | CHARGER_V | | Reg Addr: 5 | Slave Addr: D4 Default = 0x1x x100 | | | | | |
| 7 | Reserved | R | This bit returns 0. | | | | | | |
| 6 | VIN_CON | R | Mirror of INPUT_STATUS[7] (see INPUT_STATUS register description) | | | | | | |
| 5 | IO_LEVELV | R/W | 0: Output current is controlled by IOCHARGE bits for charging from VIN. When charging from VIN, the voltage across R_{SENSE} for output current control is set to 22.1mV (325mA for $R_{SENSE} = 68m\Omega$, 221mA for 100m Ω). | | | | | | |
| 4 | SPV | R | charging. | $_{N}$ is able to stay above V _{SP} . SPV = 0 when VIN is not PWM nd controlling the charging current. | | | | | |
| 3 | EN_LEVEL | R | DISABLE (DIS) pin is LOW. DISABLE (DIS) pin is HIGH | | | | | | |
| 2:0 | VSPV | R/W | | reference voltage when charging from VIN. If V _{IN} falls below ad until the input voltage is at or above V _{SP} (see Table 19). | | | | | |

| Bit | Name | Туре | | | | | [| Description | |
|---------|--------------------|------------|--|--|---|-------------------------------------|---------------------|-----------------------|-----------------------|
| SAFE_V | | | Reg Addr: 6 Slave Addr: D4 Default = 0100 0000 | | | | | | |
| | | | Any attempt to write a value to ICHGV higher than the contents of ISAFEV sets ICHGV = ISAFEV. Any attempt to write a value higher than 1010 to ISAFEV results in ISAFEV = 1010. Table 26. I _{CHARGE} Limit as a Function of the ISAFEV Bits when Charging from VIN | | | | | | |
| | | | Table 2 | 6. І _{СНА} | 1 | 1 | | of the ISAFEV Bits wi | nen Charging from VIN |
| 7:4 | | | BIN | HEX | V _{RSENSE} (mV) | I _{SAFE} 68mΩ | (mA) 100mΩ | | |
| | | | 0000 | 00 | 37.4 | 550 | 374 | | |
| | | | 0001 | 01 | 44.2 | 650 | 442 | | |
| | ISAFEV | R/W | 0010 | 02 | 51.0 | 750 | 510 | | |
| | | | 0011 0100 | 03 04 | 57.8 64.6 | 850 950 | 578 646 | | |
| | | | 0101 | 05 | 71.4 | 1,050 | 714 | | |
| | | | 0110 | 06 | 78.2 | 1,150 | 782 | | |
| | | | 0111 | 07 08 | 85.0 91.8 | 1,250 1,350 | 850 918 | | |
| | | | 1000 | 09 | 98.6 | 1,450 | 986 | | |
| | | | 1010 | 0A | 105.4 | 1,550 | 1,054 | | |
| 3:0 | VSAFEV | R/W | Any attempt to write a value to OREGV that is higher than the value in the Max OREG column below results in OREGV = Max OREG (see Table 21). | | | | the Max OREG column | | |
| | | | | | _ | | | | |
| Bit | Name | Туре | | | | | 0 | Description | |
| LED | _CONTROL | | F | Reg Ad | dr: 7 | | | Slave Addr: D4 or D6 | Default = 1000 0010 |
| | | R/W | Sets LED | behavi | or | | | | |
| | | | Table 27 | . LED | Contro | l Bits | | | |
| | I_LED | | | D is off | | | | | |
| 7:6 | | | | | nt = 1.13 | mΔ | | | |
| | | | | | | | | | |
| | | | - | | ont = 2 2 | | | | |
| | | | 10 LE | D curre | ent = 2.2 | 5mA | | | |
| _ | Description | | 10 LE | D curre D curre | nt = 4.50 | 5mA | | | |
| 5 | Reserved | R | 10LE11LEThis bit re | D curre D curre eturns 0 | nt = 4.50 | 5 mA mA | | | |
| _ | Reserved LED_ON | R R/W | 10 LE 11 LE This bit re 0: LED | D curre D curre eturns 0 is only | nt = 4.50 y active v | 5mA mA when cha | | totus | |
| 5 | | | 10 LE 11 LE This bit re 0: LED 1: LED | D curre D curre eturns 0 is only is activ | nt = 4.50 y active v ve regard | 5 mA mA | | tatus. | |
| 5 | | | 10 LE 11 LE This bit re 0: LED 1: LED Sets LED | D curre eturns 0 is only is activ | nt = 4.50 y active v ve regard | 5mA mA when cha less of ch | | atus. | |
| 5 | | | 10 LE 11 LE This bit re 0: LED 1: LED Sets LED Table 28 | D curre D curre eturns 0 is only is activ blink t _c B. LED | nt = 4.50 y active v ve regard | 5mA mA when cha less of ch | | atus. | |
| 5 4 | LED_ON | R/W | 10 LE 11 LE This bit re 0: LED 1: LED Sets LED Table 28 | D curre eturns 0 is only is activ | nt = 4.50 y active v ve regard | 5mA mA when cha less of ch | | tatus. | |
| 5 | | | 10 LE 11 LE This bit re 0: LED 1: LED Sets LED Table 28 00 13 | D curre D curre eturns 0 is only is activ blink t _c B. LED | nt = 4.50 y active v ve regard | 5mA mA when cha less of ch | | tatus. | |
| 5 | LED_ON | R/W | 10 LE 11 LE This bit re 0: LED 1: LED Sets LED Table 28 00 13: 01 26: | D curre D curre eturns 0 is only is activ blink to B. LED 1 ms | nt = 4.50 y active v ve regard | 5mA mA when cha less of ch | | tatus. | |
| 5 | LED_ON | R/W | 10 LE 11 LE This bit re 0: LED 1: LED Sets LED Table 28 00 13: 01 26: 10 524 | D curre D curre eturns 0 is activ blink tc B. LED 1 ms 2 ms | nt = 4.50 y active v ve regard DN O ON-Tin | 5mA mA when cha less of ch | | atus. | |
| 5 | LED_ON | R/W | 10 LE 11 LE This bit re 0: LED 1: LED Sets LED Table 28 00 13: 01 26: 10 524 | D curre D curre eturns 0 is activ blink tc B. LED 1 ms 2 ms 4 ms nstant (| nt = 4.50 y active v ve regard N ON-Tin | 5mA mA when cha less of ch | | tatus. | |
| 5 | LED_ON | R/W | 10 LE 11 LE This bit re 0: LED 1: LED Sets LED Table 28 00 13: 01 26: 10 52: 11 Co Sets LED Sets LED | D curre D curre eturns 0 is only is activ blink tc 3. LED 1 ms 2 ms 4 ms nstant (blink tc | nt = 4.50 y active v ve regard DN DON DON DFF | 5mA mA when cha less of ch | | tatus. | |
| 5 | LED_ON | R/W | 10 LE 11 LE This bit re 0: LED 1: LED Sets LED Table 28 00 13 01 262 10 524 11 Co Sets LED Table 28 | D curre D curre eturns 0 is activ blink tc 3. LED 1 ms 2 ms 4 ms nstant (blink tc 0. LED | nt = 4.50 y active v ve regard DN DON DON DFF | 5mA mA when cha less of ch | | atus. | R |
| 5 | LED_ON | R/W | 10 LE 11 LE This bit re 0: 0: LED 1: LED Sets LED Table 28 00 13: 01 26: 10 52: 11 Co Sets LED Table 29 00 39: | D curre D curre eturns 0 is activ blink tc B. LED 1 ms 2 ms 4 ms nstant (blink tc D. LED 3 ms | nt = 4.50 y active v ve regard DN DON DON DFF | 5mA mA when cha less of ch | | tatus. | B |
| 5 4 3:2 | LED_ON | R/W R/W | 10 LE 11 LE This bit re 0: LED 1: LED Sets LED Table 28 00 13' 01 26' 10 52-4 11 Co Sets LED Table 28 00 13' 01 26' 10 52-4 11 Co Sets LED Table 29 00 393' 01 780 | D curre D curre eturns 0 is activ blink tc B. LED 1 ms 2 ms 4 ms nstant (blink tc 0. LED 3 ms 6 ms | nt = 4.50 y active v ve regard DN DON DON DFF | 5mA mA when cha less of ch | | tatus. | B |
| 5 4 3:2 | LED_ON | R/W R/W | 10 LE 11 LE This bit re 0: LED 1: LED Sets LED Table 28 00 13: 01 26: 10 52:4 11 Co Sets LED Table 28 00 13: 01 26:2 10 52:4 11 Co Sets LED Table 29 00 39: 01 78: 10 15: | D curre D curre eturns 0 is activ blink tc B. LED 1 ms 2 ms 4 ms nstant (blink tc D. LED 3 ms | nt = 4.50 y active v ve regard DN DON DON DFF | 5mA mA when cha less of ch | | tatus. | B |

| Bit | Name | Туре | | Description | | | |
|-----|-------------|------|---|---|--|--|--|
| CHA | ARGE_STATUS | 5 | Reg Addr: 8 | Slave Addr: D4 or D6 | | | |
| 7 | ITERM_CMP | R | 0: If TE = 1, $(V_{CSIN} - V_{BAT}) < V_{ITERM}$. If TE = 0, $(V_{CSIN} - V_{BAT}) < 1 \text{ mV}$. 1: If TE = 0, $(V_{CSIN} - V_{BAT}) > V_{ITERM}$. If TE = 0, $(V_{CSIN} - V_{BAT}) > 1 \text{ mV}$. | | | | |
| 6 | T_120 | R | 0: The die temperature is below 120°C.1: The die temperature is above 120°C. | | | | |
| 5 | ICHG | R | ICHARGE loop is controlling charge current (charger is in CC Mode). ICHARGE loop is not controlling charge current. | | | | |
| 4 | IBUS | R | 0: IBUS is limiting charge current. 1: IBUS loop is not controlling charge current. This bit always = 1 when charging from VIN. | | | | |
| 3 | CV | R | 1 indicates that the constant-voltage loop (OREG) is controlling the charger and that all current limiting loops have released. Deglitched 32ms. | | | | |
| 2 | LINCHG | R | 0: Charger is not in Linear Mode 1: Charger is in Linear Mode (V_{BAT} < V_{SHORT}). | | | | |
| 1:0 | Reserved | R | These bits always return 0. | | | | |
| INP | UT_STATUS | | Reg Addr: 9 | Slave Addr: D4 or D6 | | | |
| 7 | VIN_CON | R | 0: V_{IN} has been less than V_{BAT} for at least 100ms (VIN is disconnected). 1: V_{IN} > V_{BAT} and V_{IN} > 4.5 V for at least 4ms (VIN is connected). This bit is mirrored in SP_CHARGER_U[3] and SP_CHARGER_V[6]. | | | | |
| 6 | VIN_VALID | R | V_{IN} has not passed validation V_{IN} has passed validation and | I can be used as a charging source. | | | |
| 5 | VBUS_CON | R | | for at least 100ms (VBUS is disconnected). for at least 4ms (VBUS is connected). | | | |
| 4 | VBUS_VALID | R | V_{BUS} has not passed validatio V_{BUS} has passed validation ar This bit is mirrored in SP_CHARGE | nd can be used as a charging source. | | | |
| 3 | SOURCE | R | $\begin{array}{llllllllllllllllllllllllllllllllllll$ | | | | |
| 2:0 | Reserved | R | These bits always return 0. | | | | |



Product-Specific Dimensions

| Product | D | E | X | Y |
|-------------|-----------------|----------------|----------|----------|
| FAN54300UCX | 2.460 ±0.030 mm | 2.26 ±0.030 mm | 0.330 mm | 0.230 mm |

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PRODUCT STATUS DEFINITIONS

| Definition | of Torme | |
|------------|----------|--|
| Definition | or remis | |

| Datasheet Identification | Product Status | Definition | | | |
|---|-----------------------|---|--|--|--|
| Advance Information | Formative / In Design | Datasheet contains the design specifications for product development. Specifications may change in any manner without notice. | | | |
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